

Figure 1

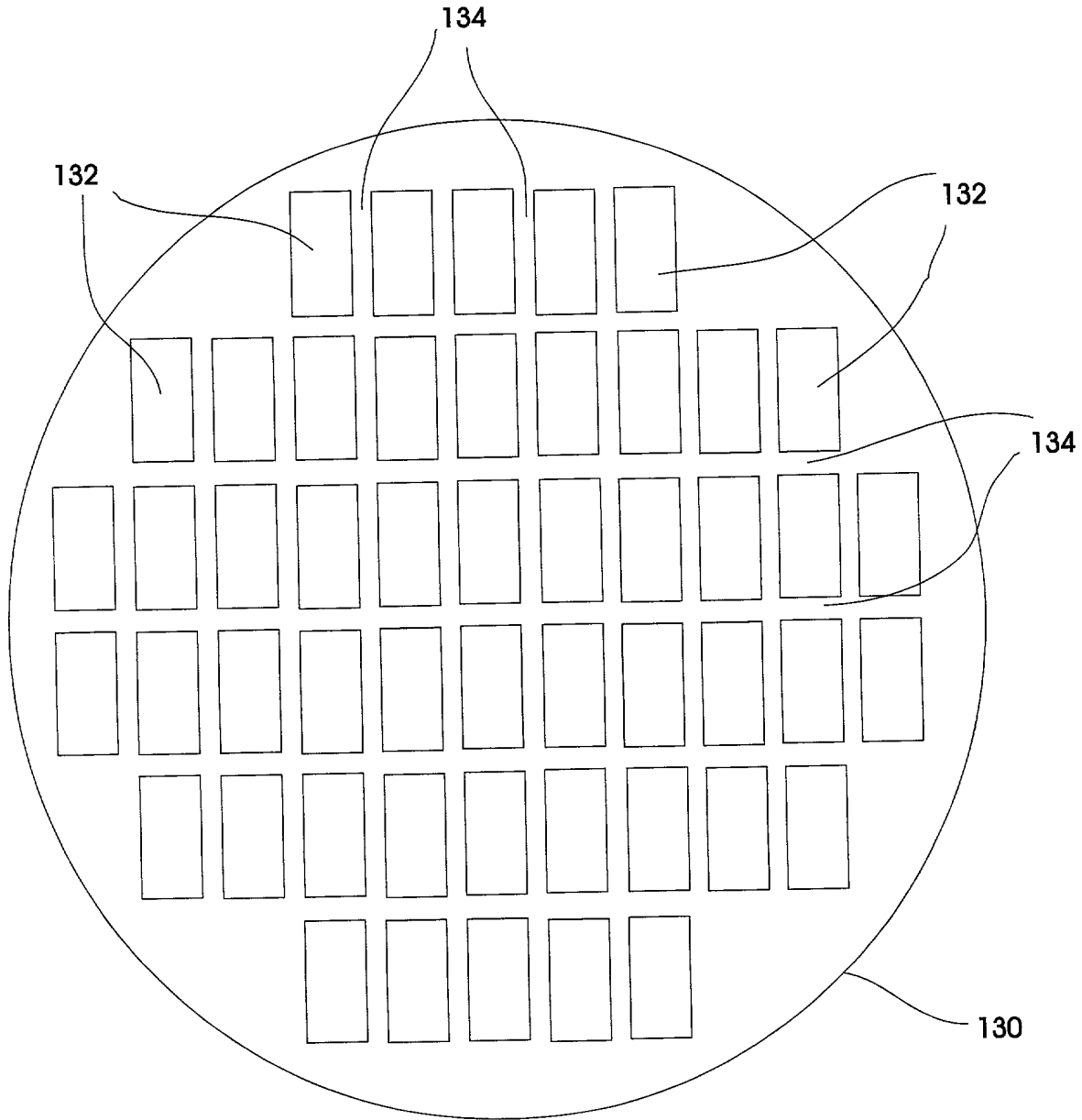


Figure 2

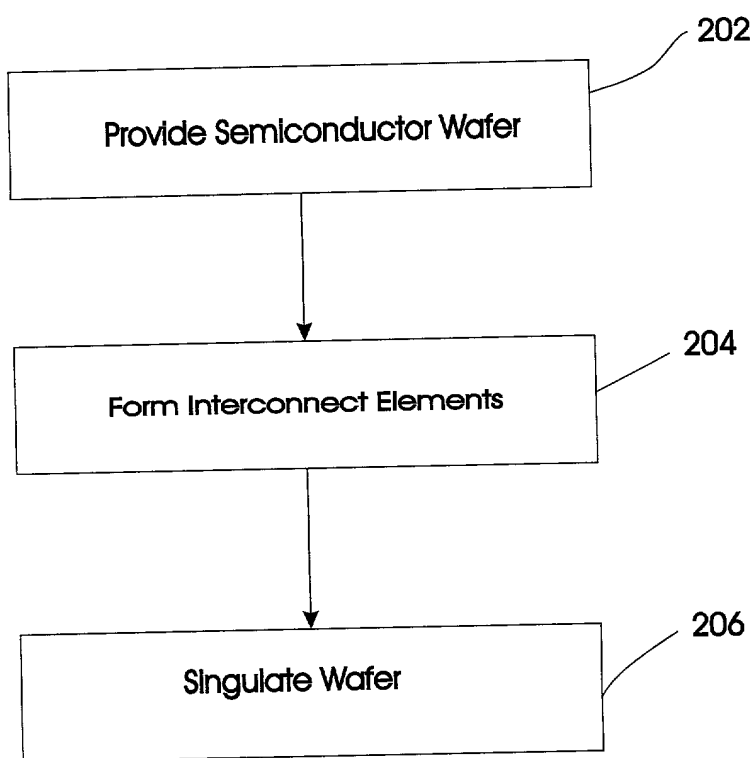


FIG. 3A

Figure 3A

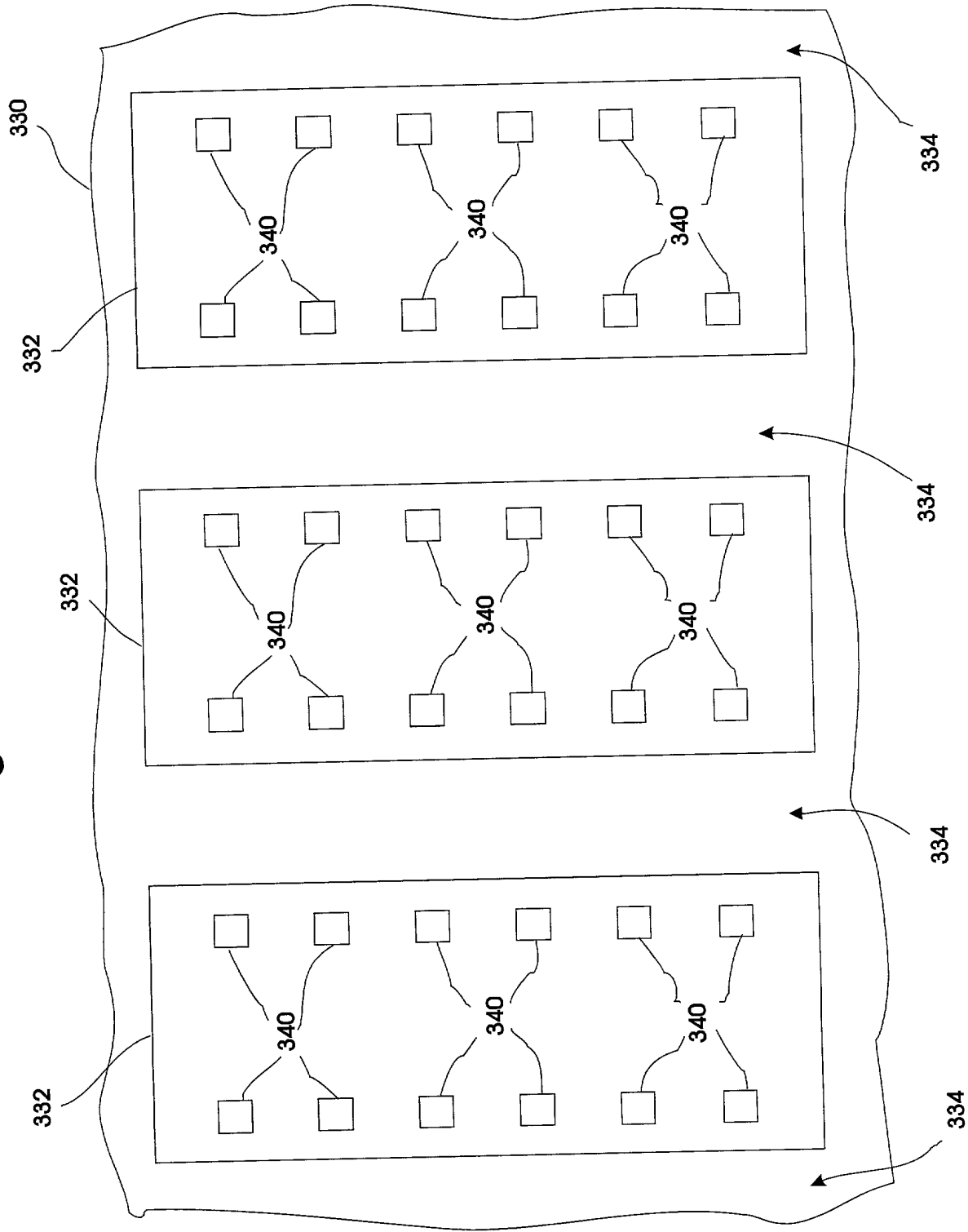


Figure 3B

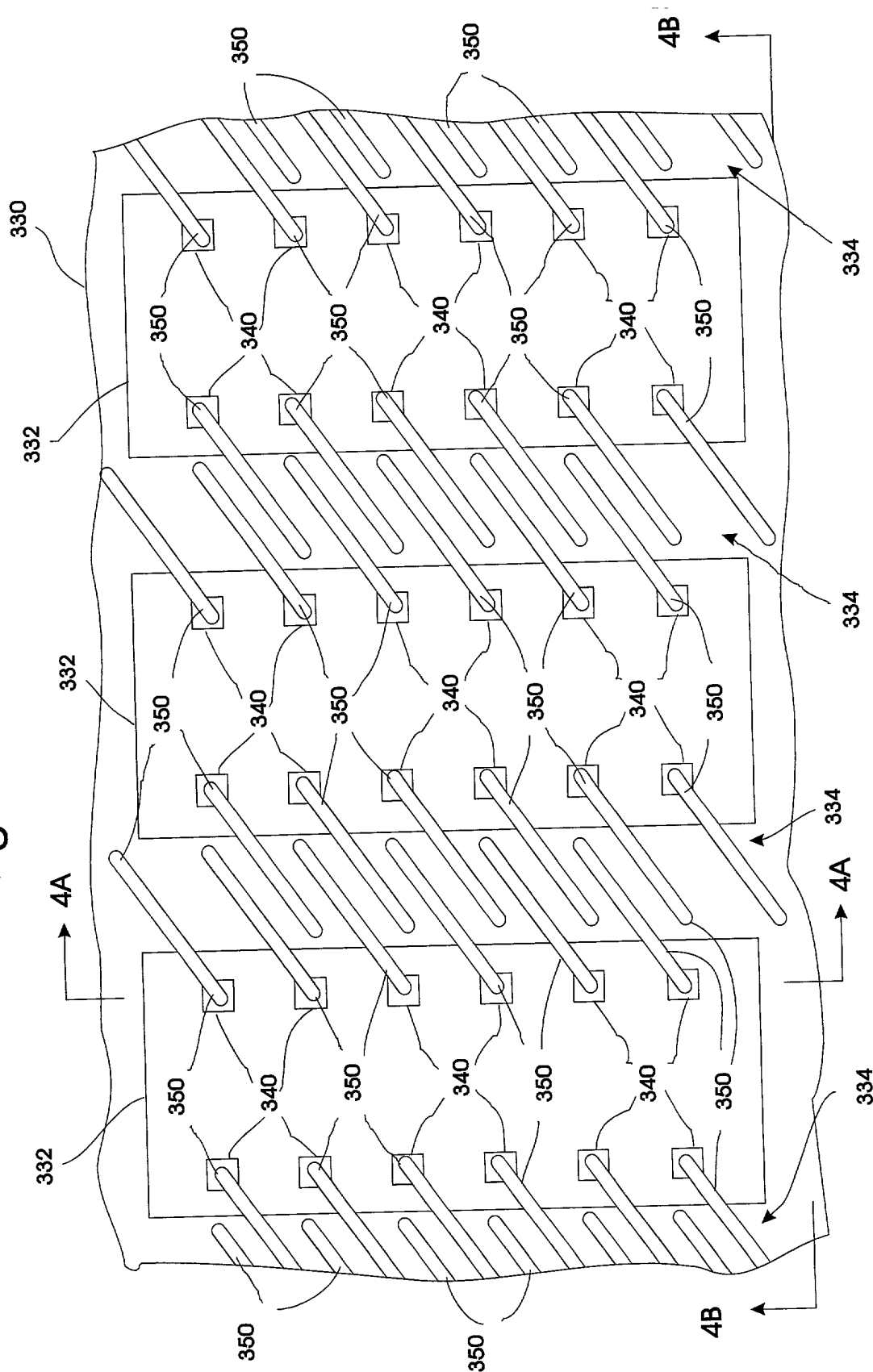


Figure 4A

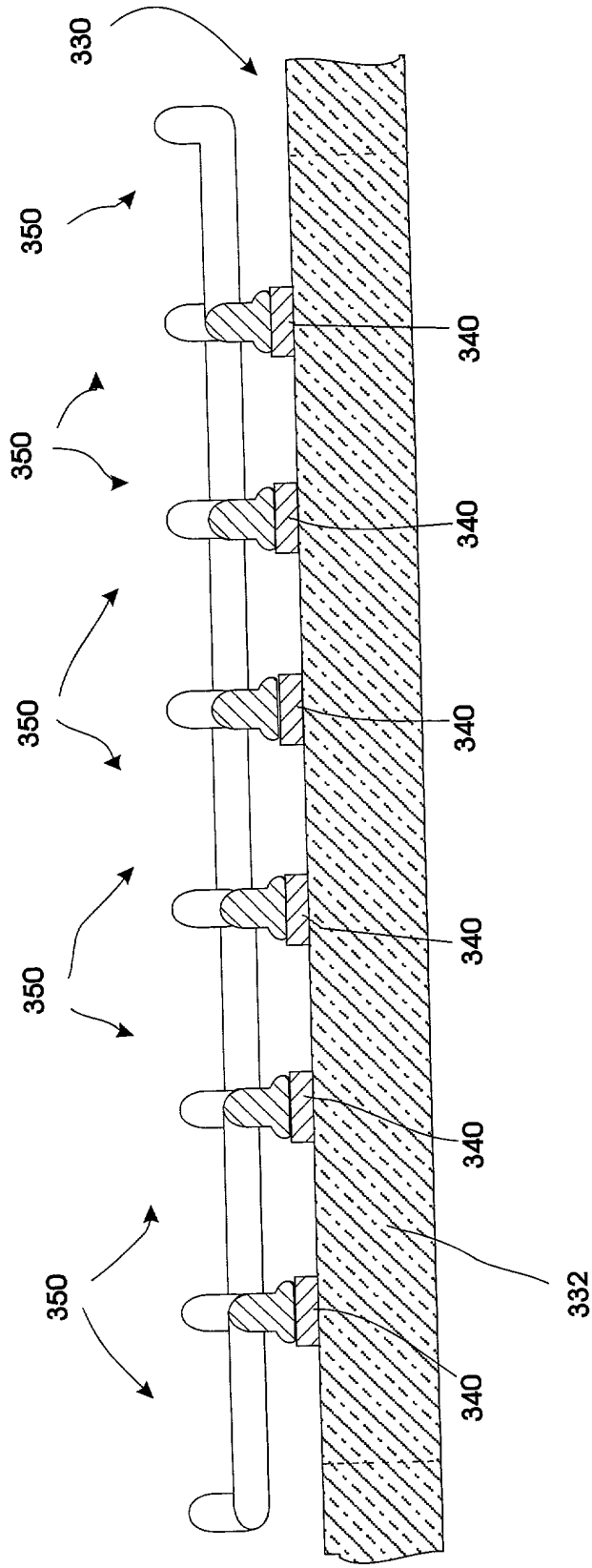


Figure 4B

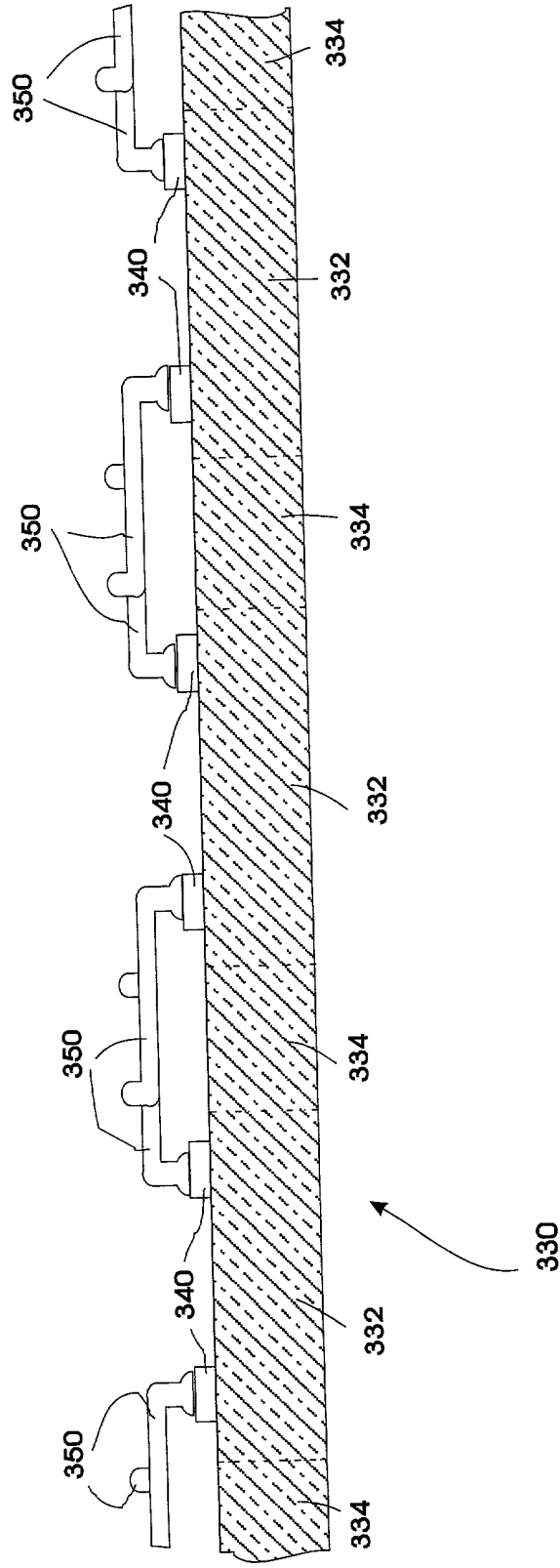


Figure 5

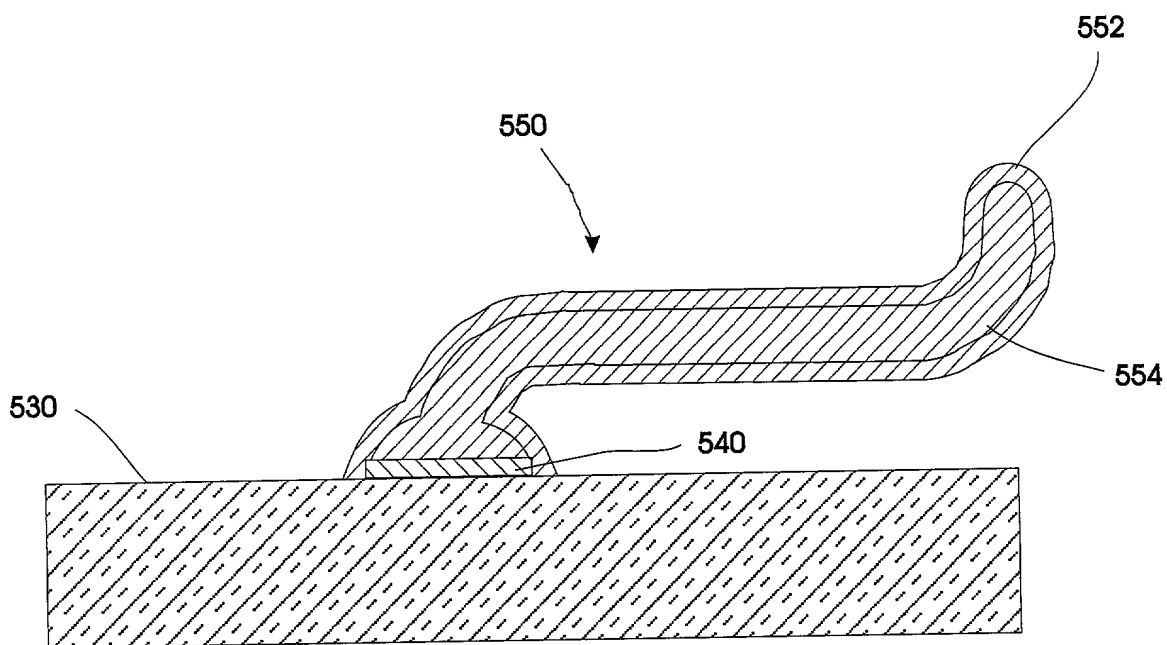


FIG. 5

Figure 6A

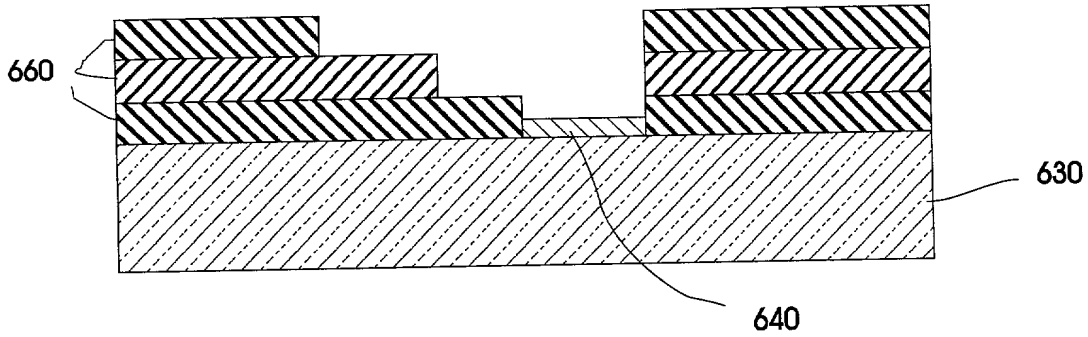


Figure 6B

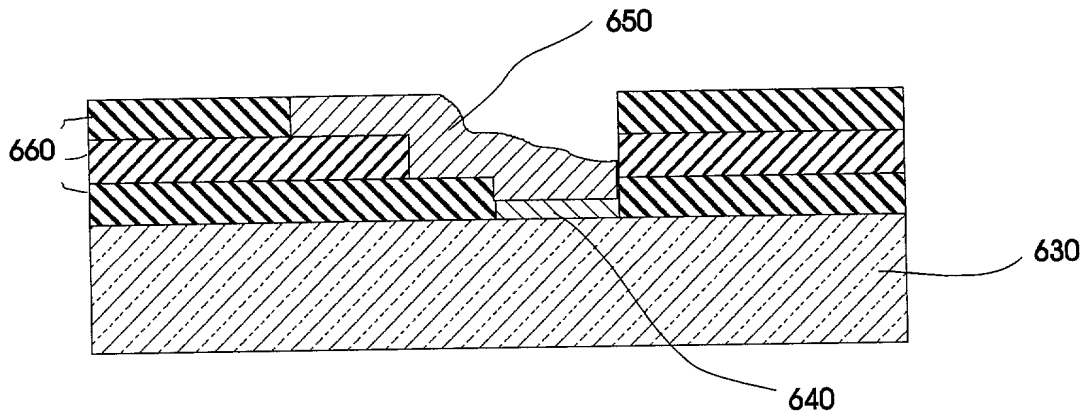


Figure 6C

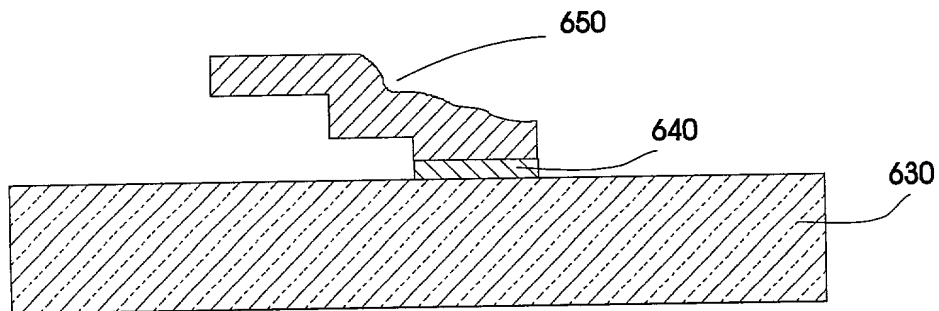




Figure 7A

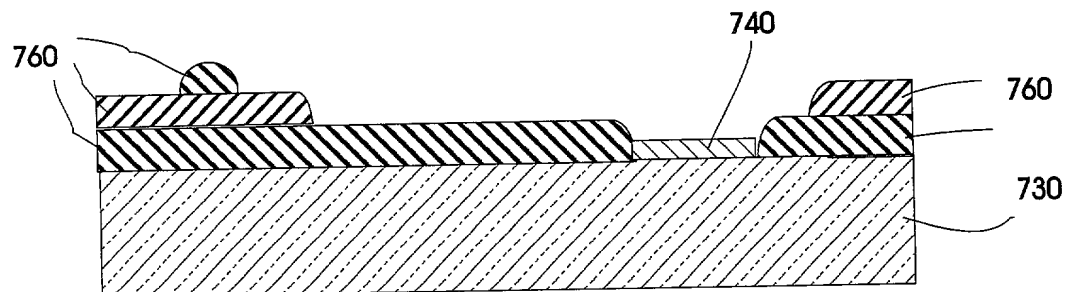


Figure 7B

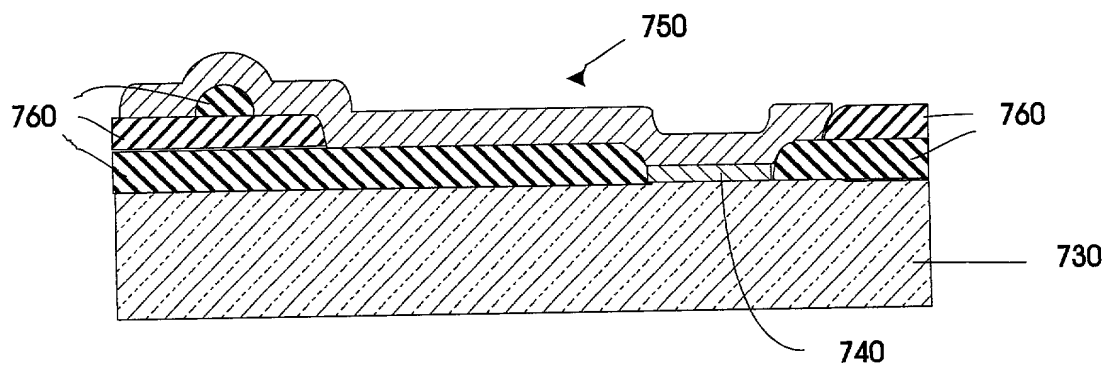


Figure 7C

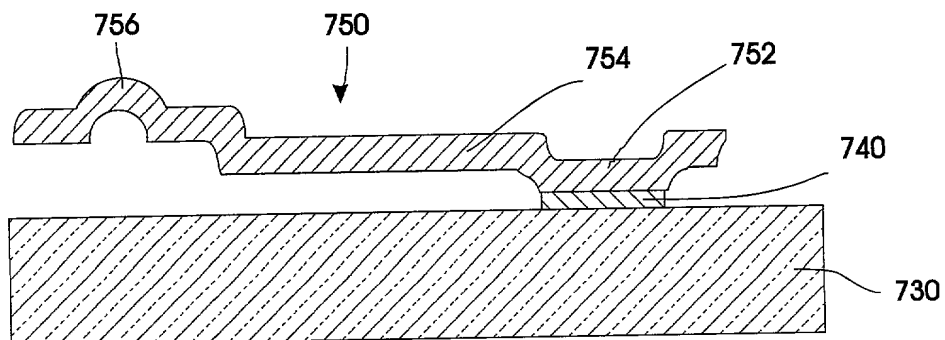


Figure 8A

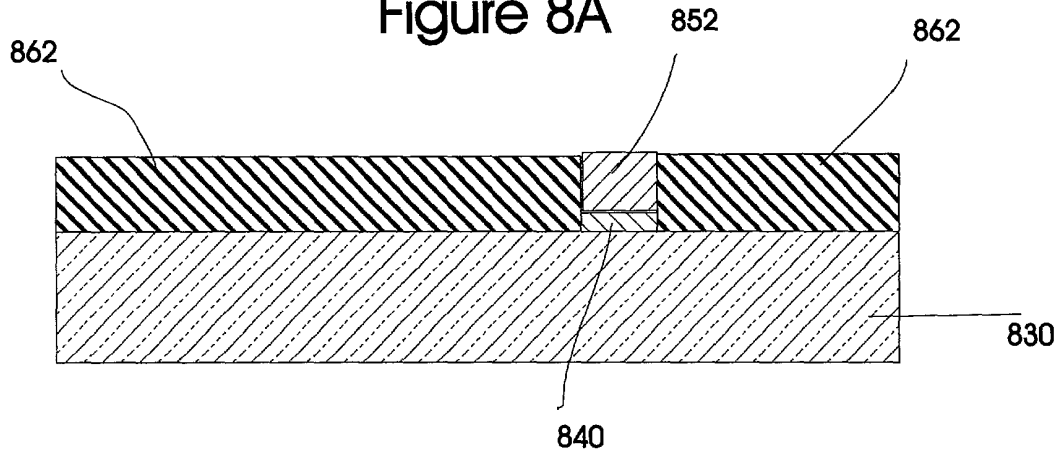


Figure 8B

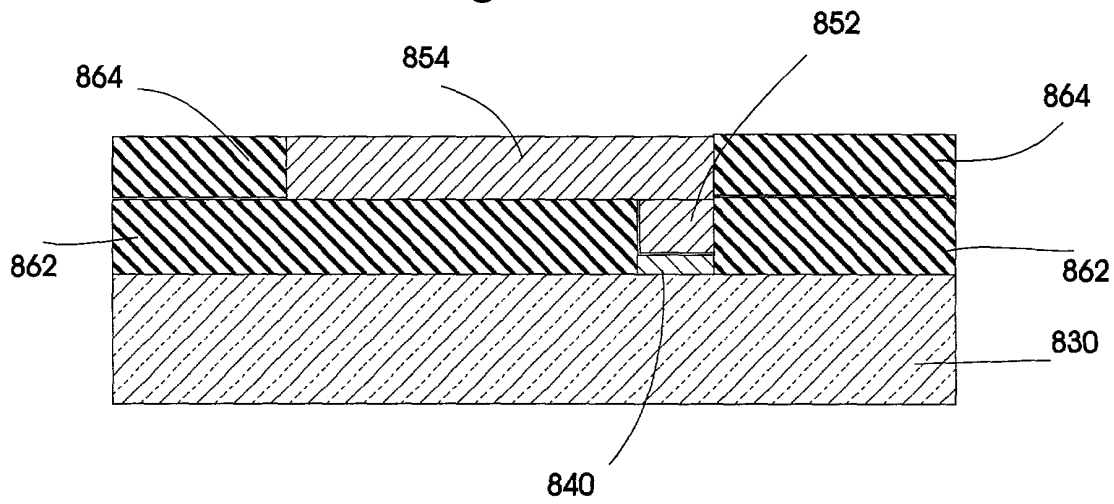


Figure 8C

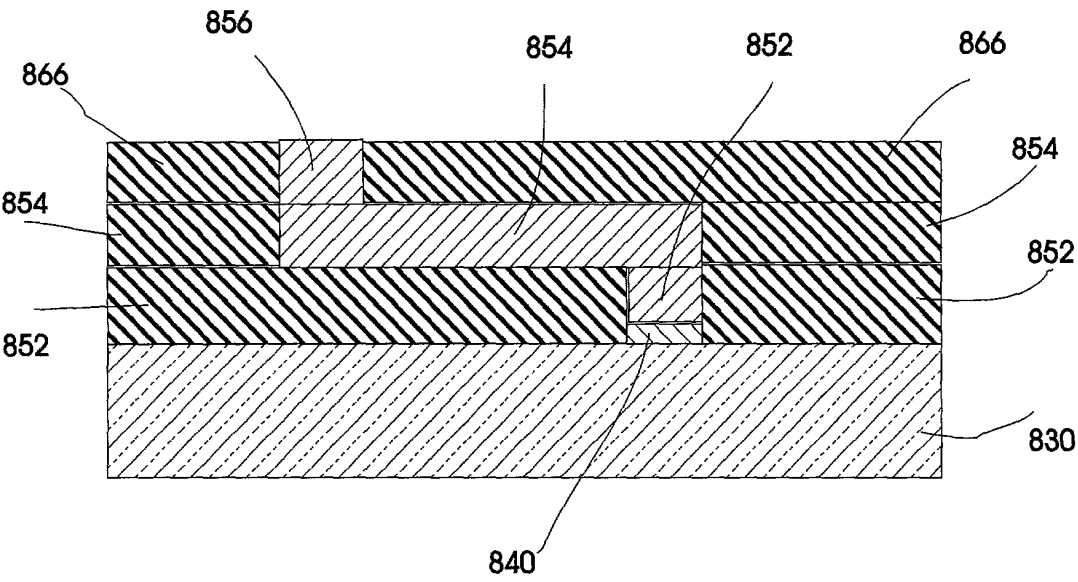


Figure 8D

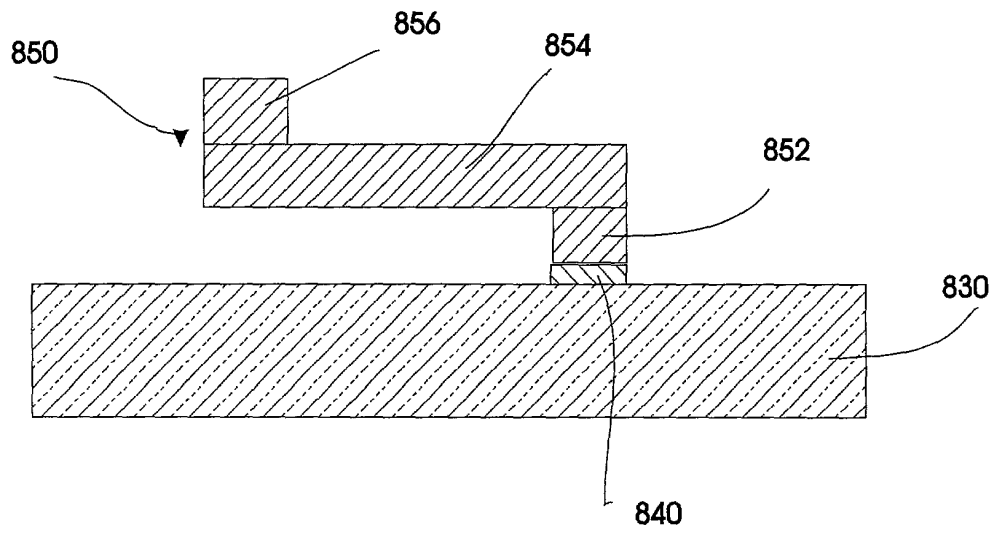


Figure 9A

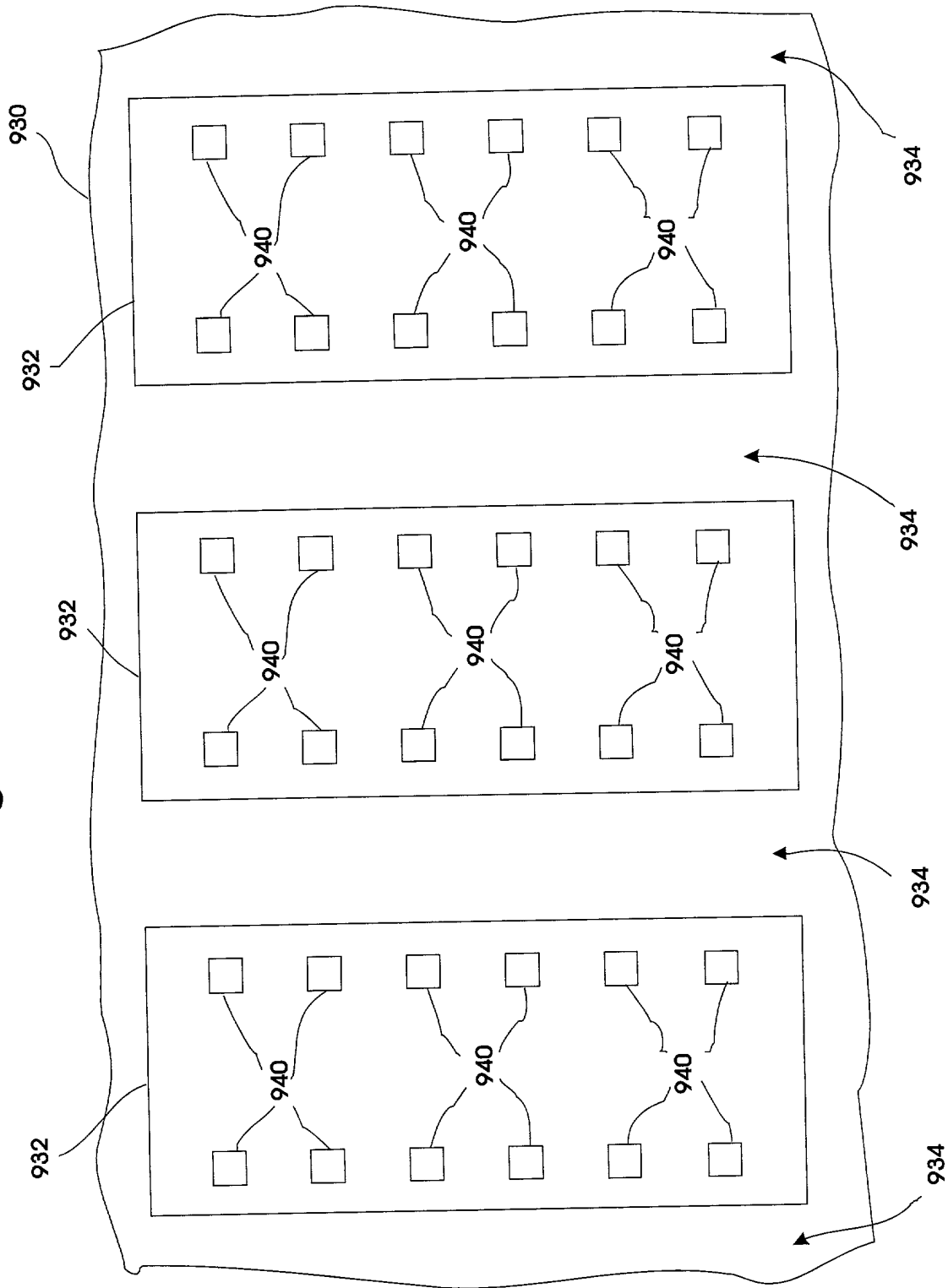


Figure 9B

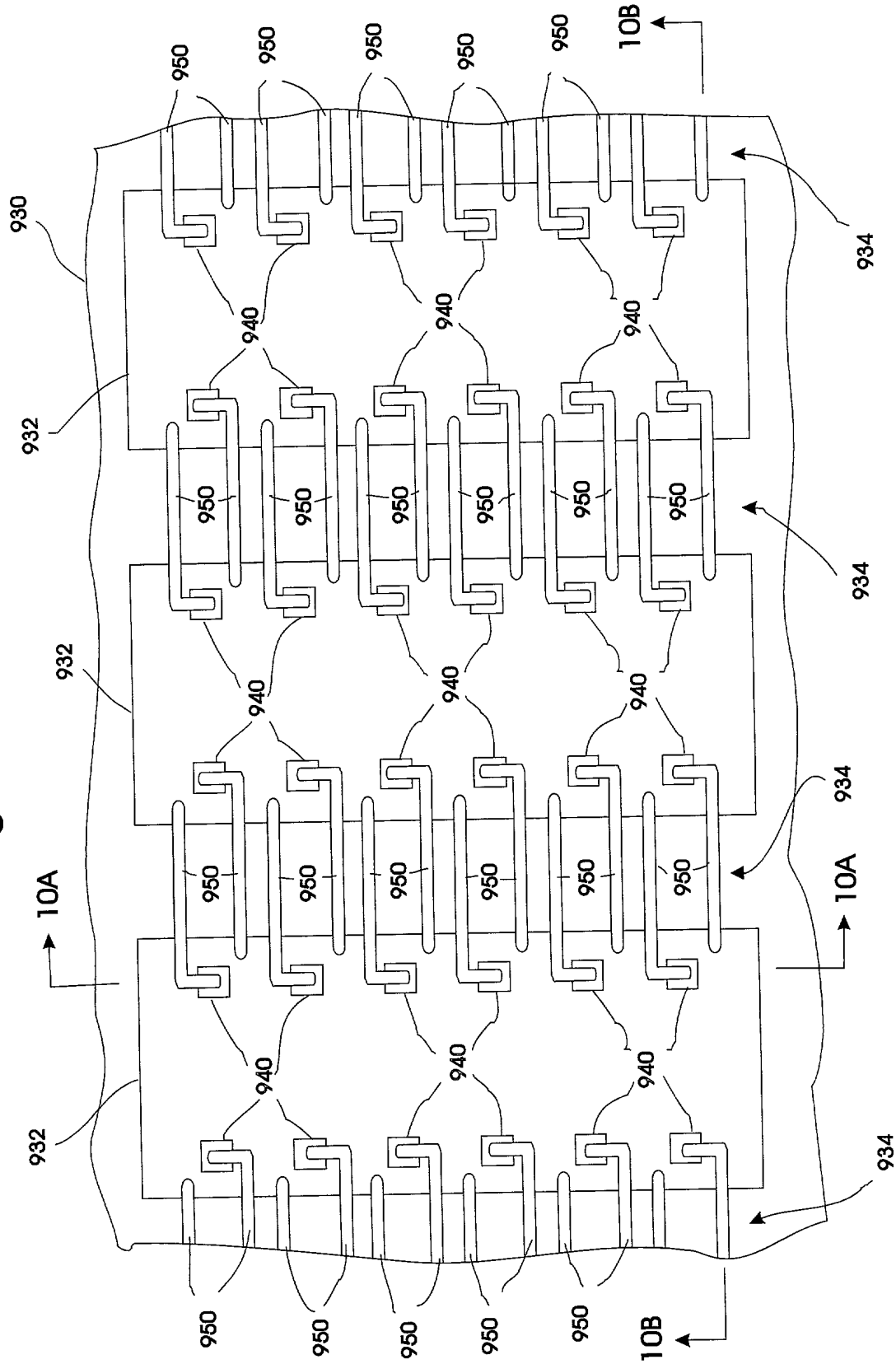


Figure 10A

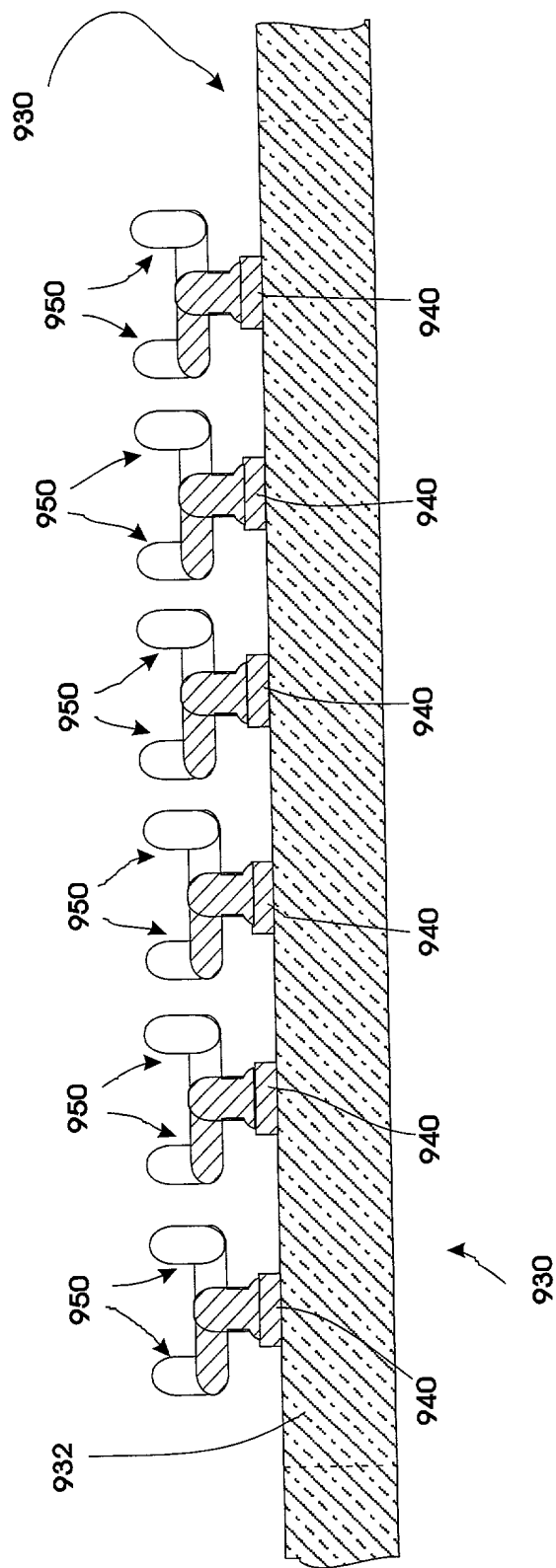


Figure 10B

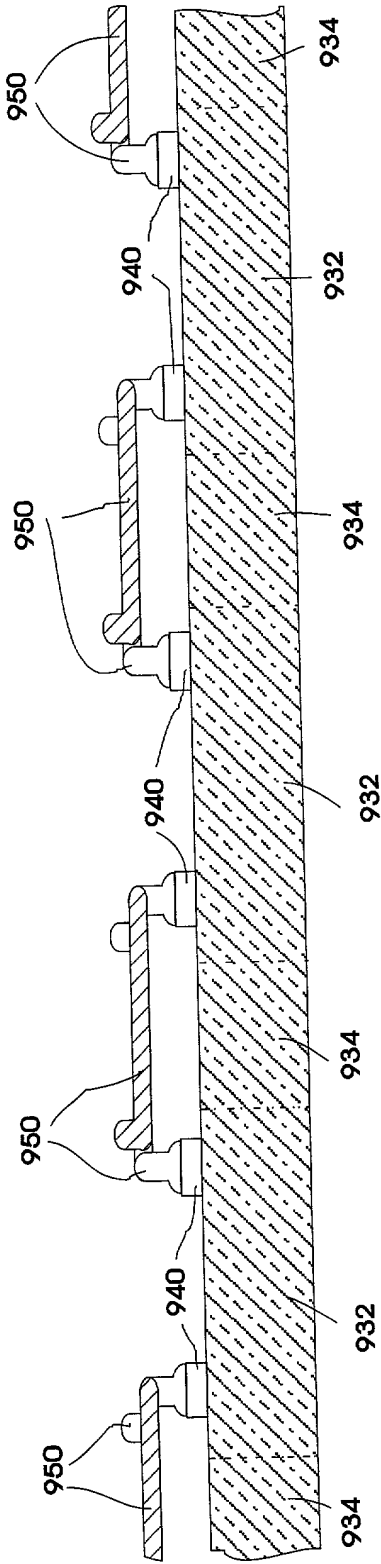


Figure 11A

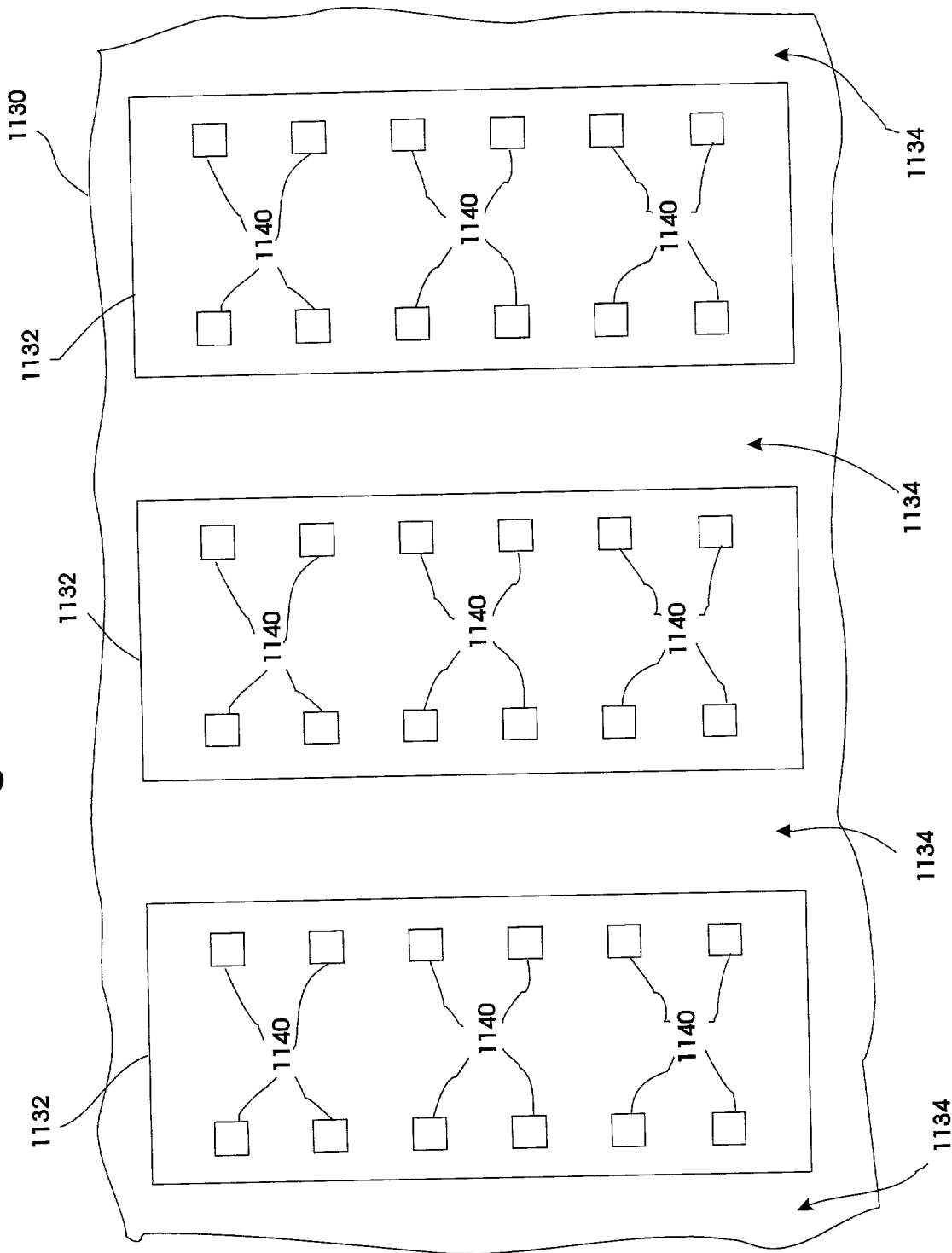




Figure 11B

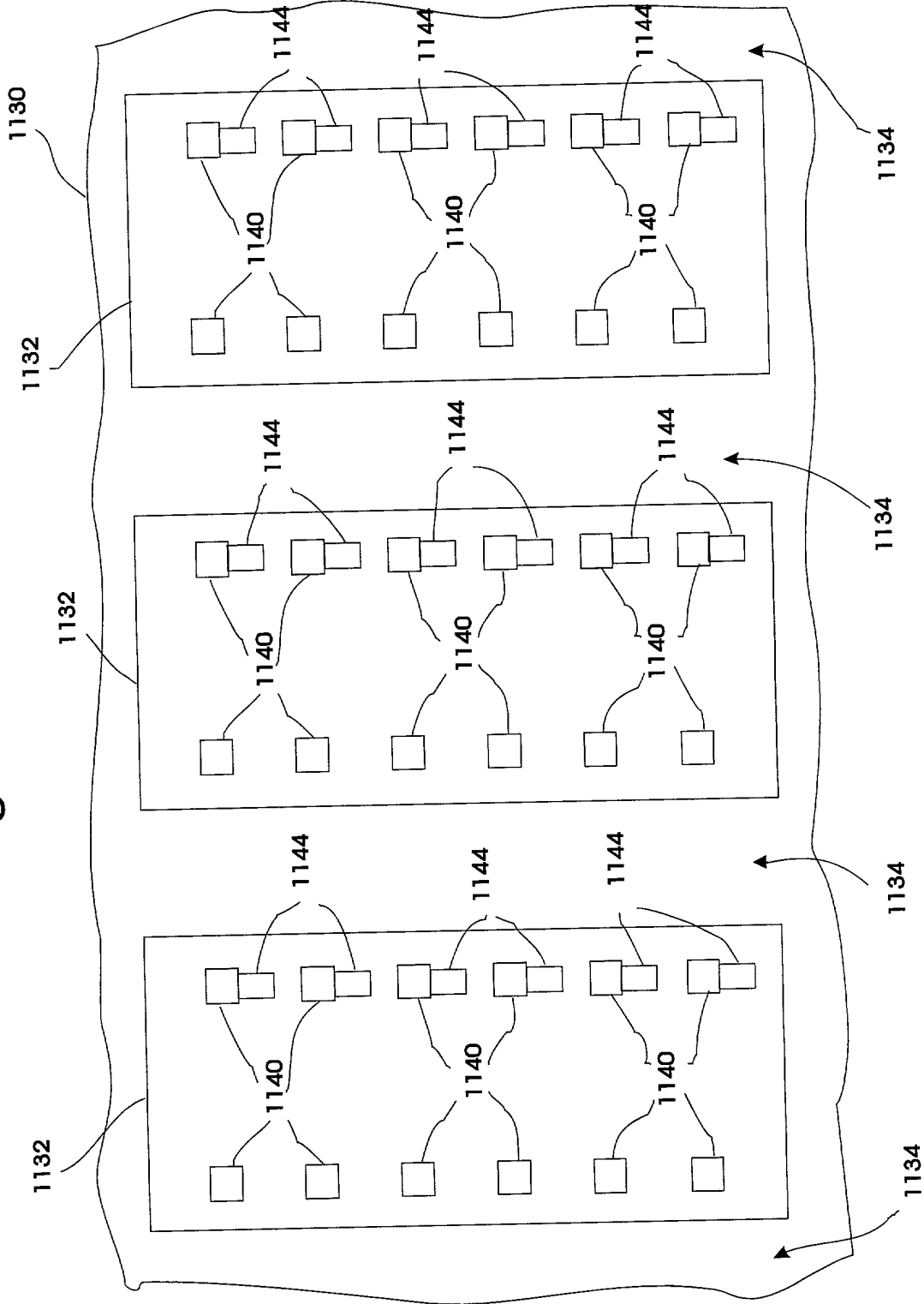


Figure 11C

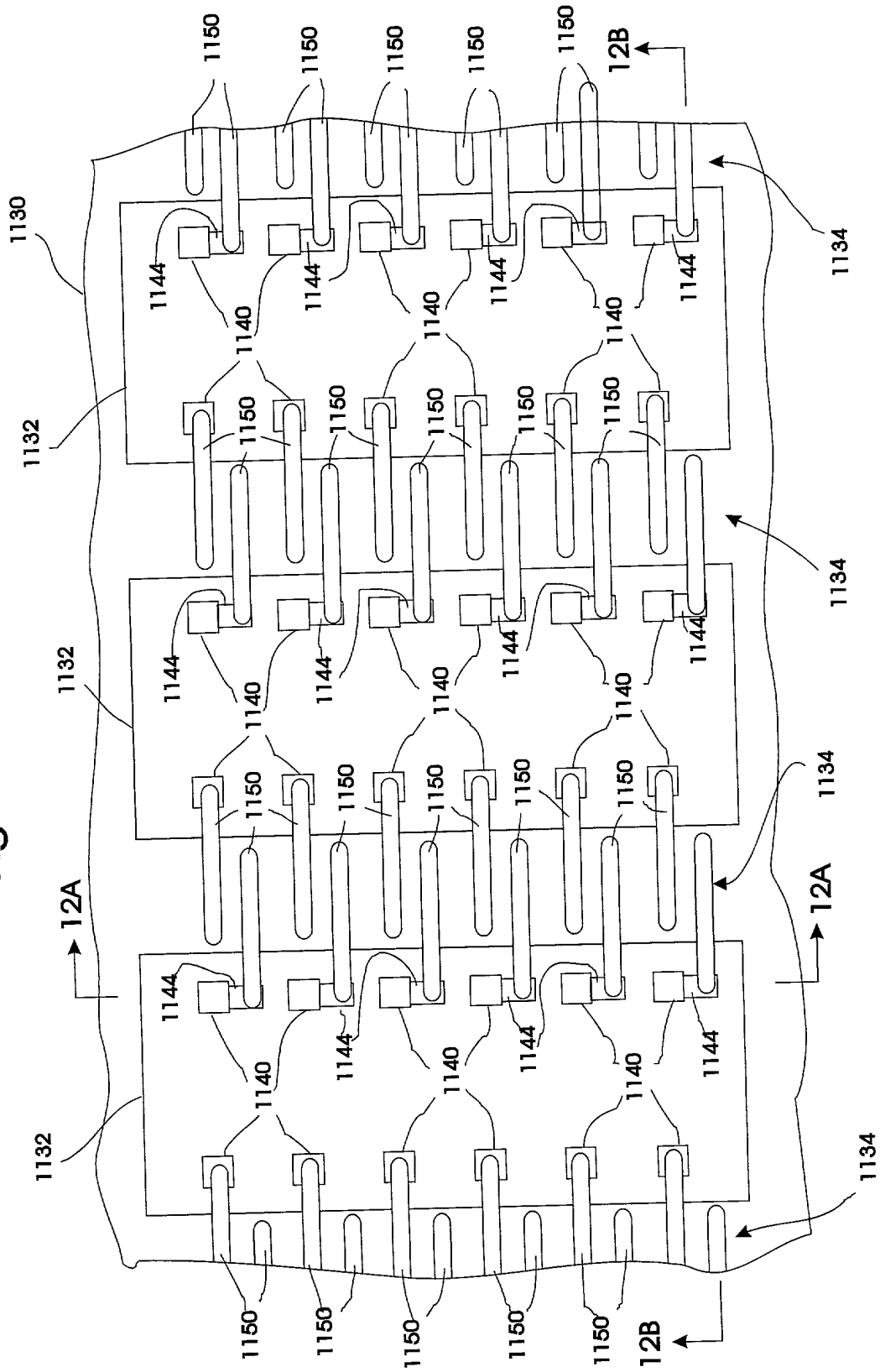


Figure 12A

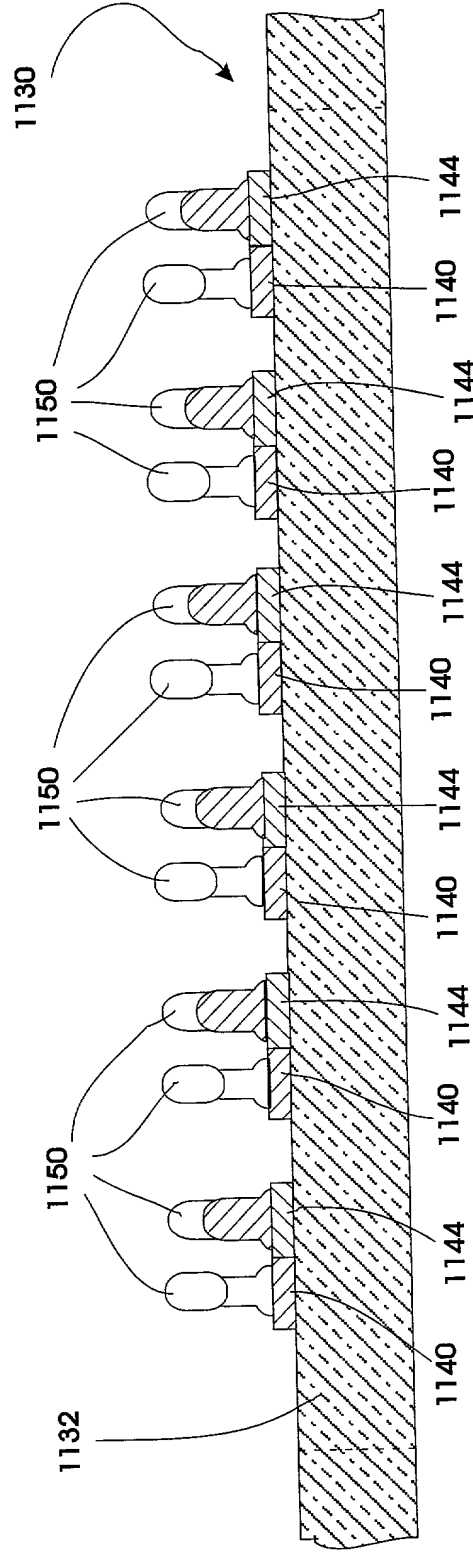


Figure 12B

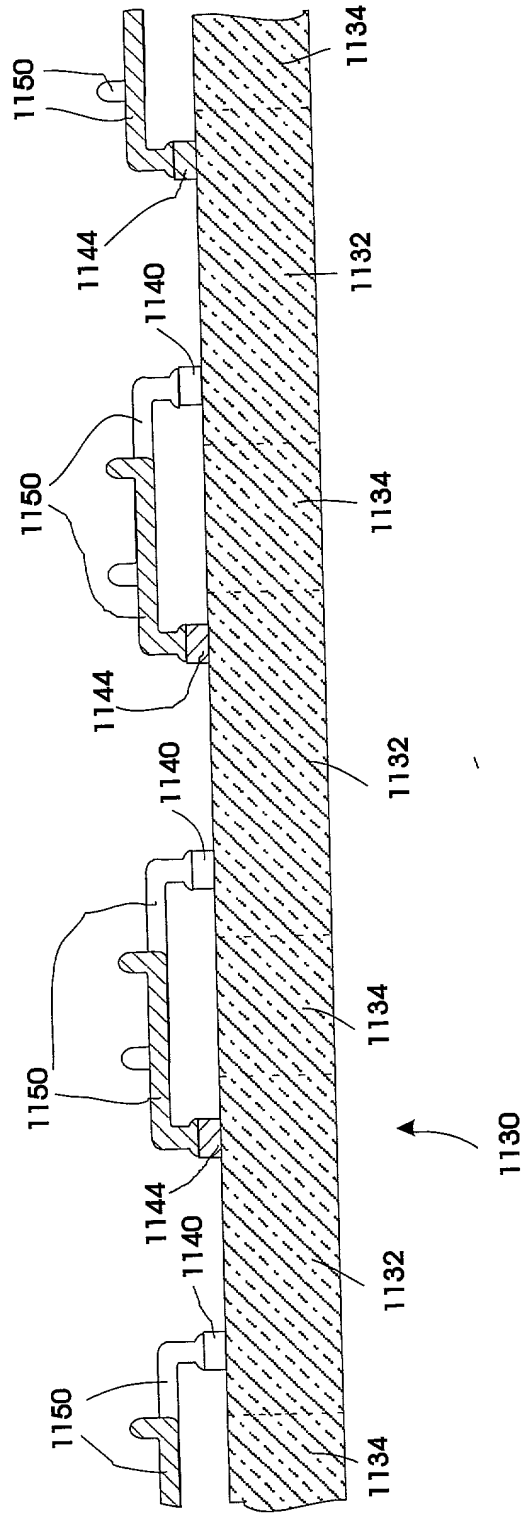


Figure 13A

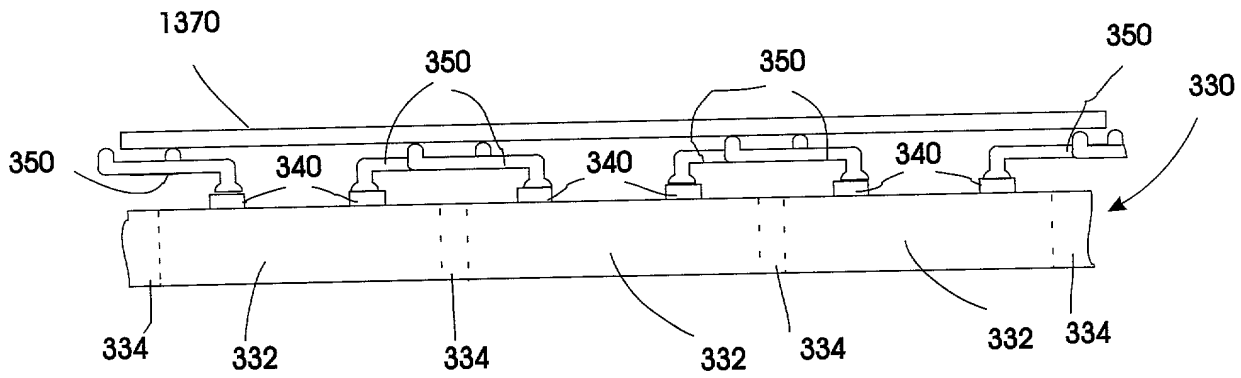


Figure 13B

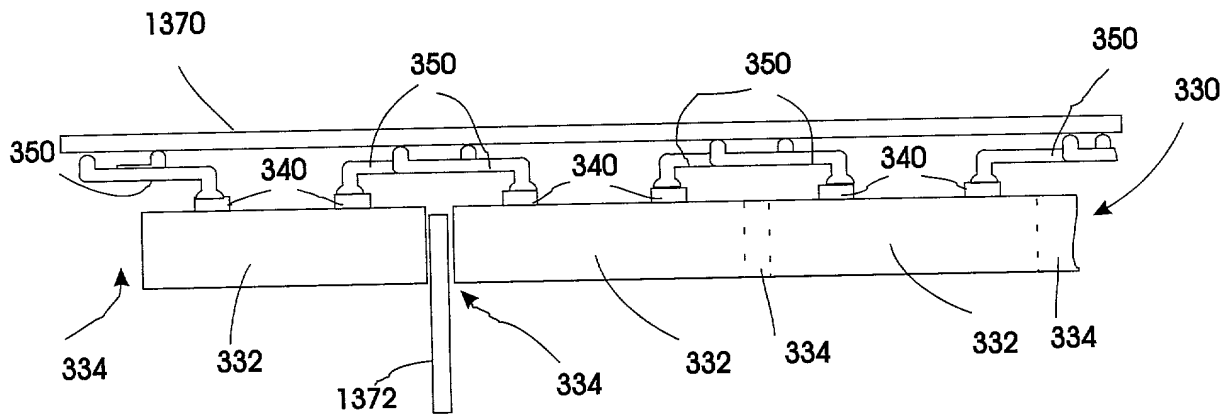


Figure 13C

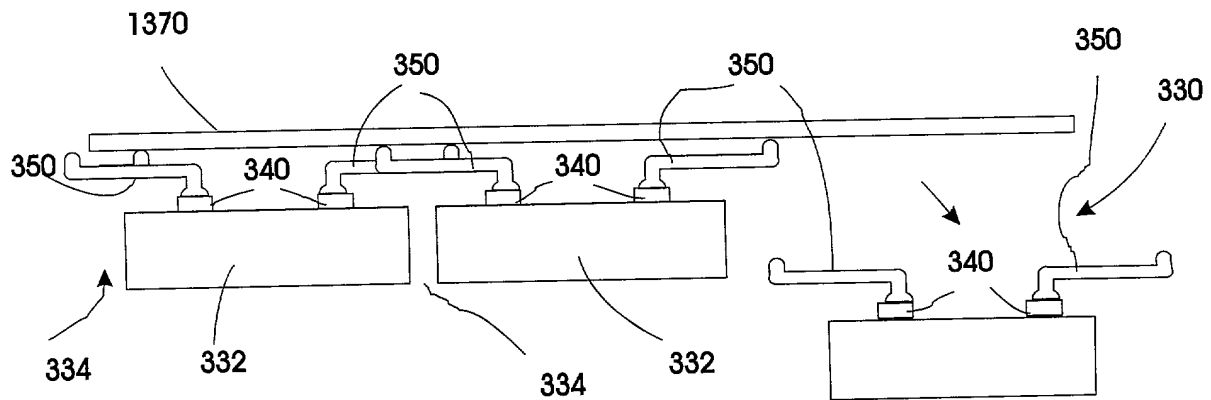


Figure 14A

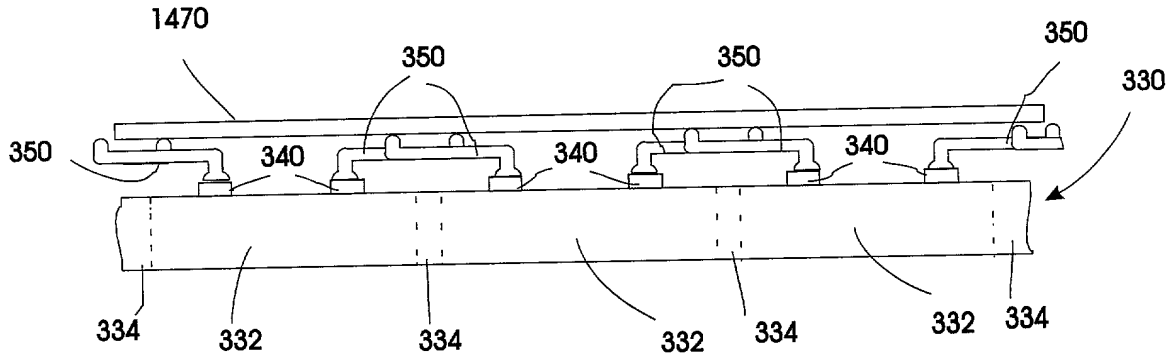


Figure 14B

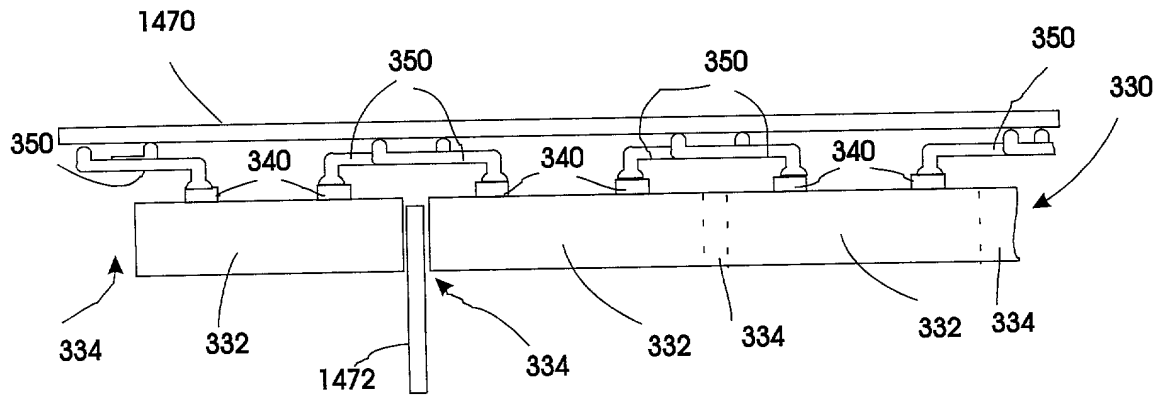


Figure 14C

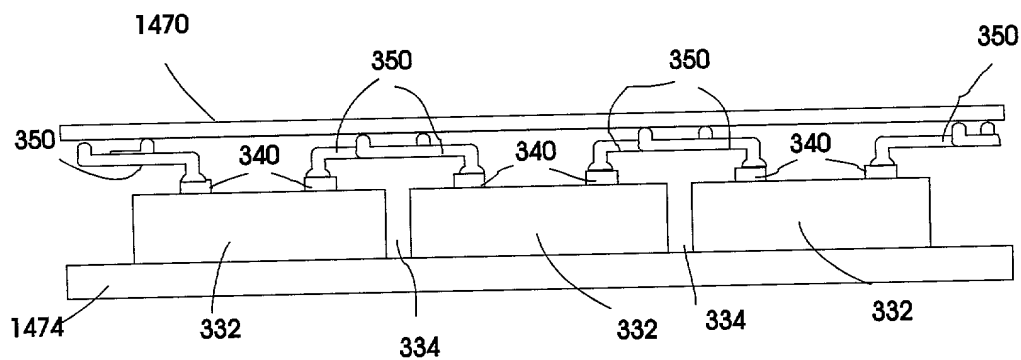


Figure 14D

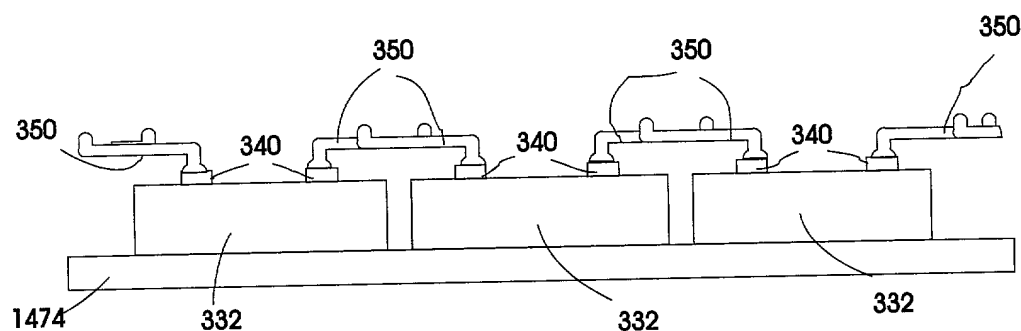


Figure 14E

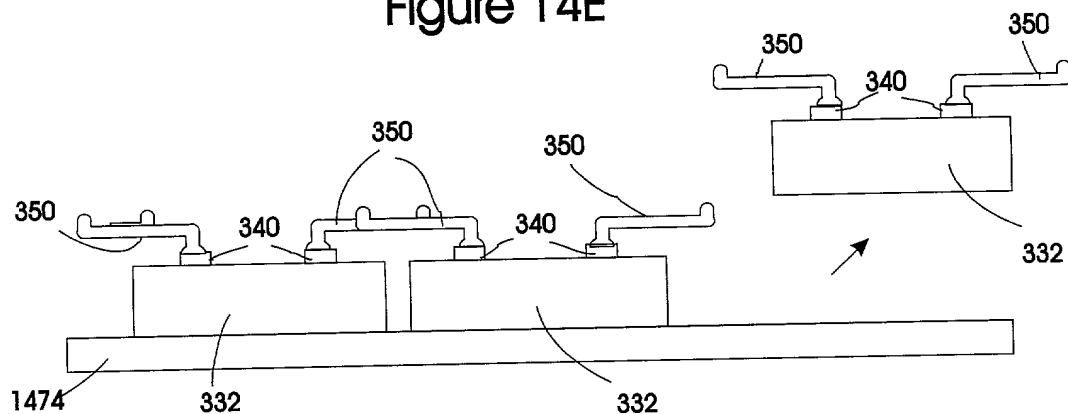


Figure 15A

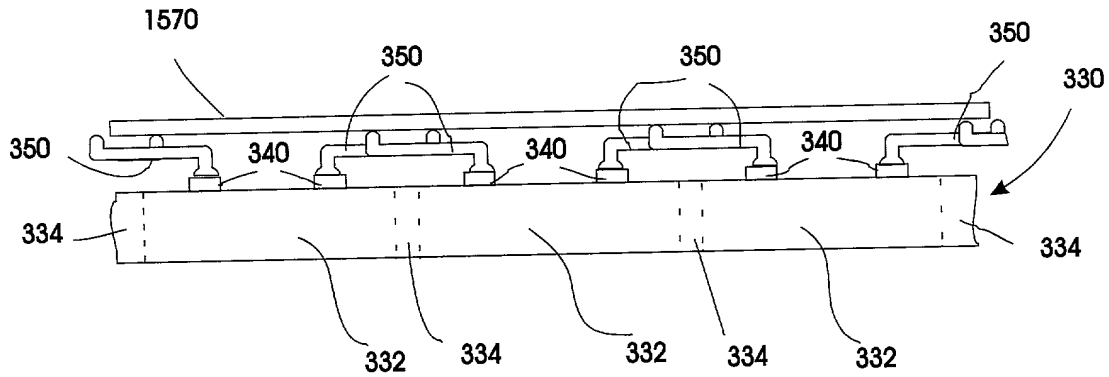


Figure 15B

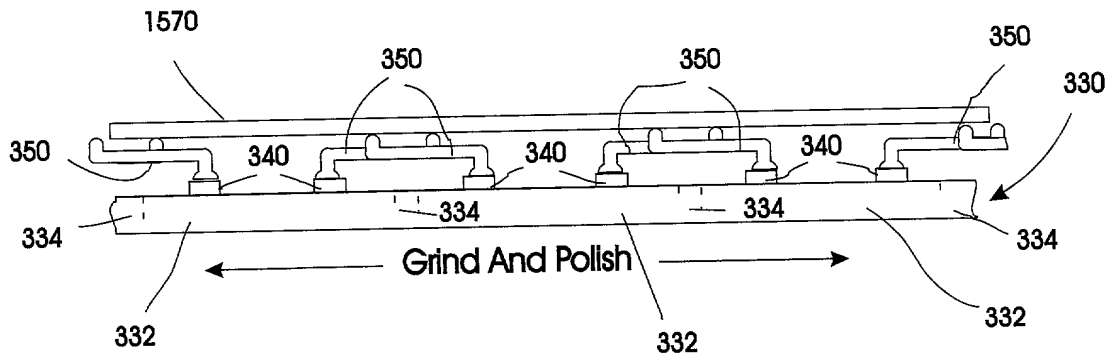




Figure 15C

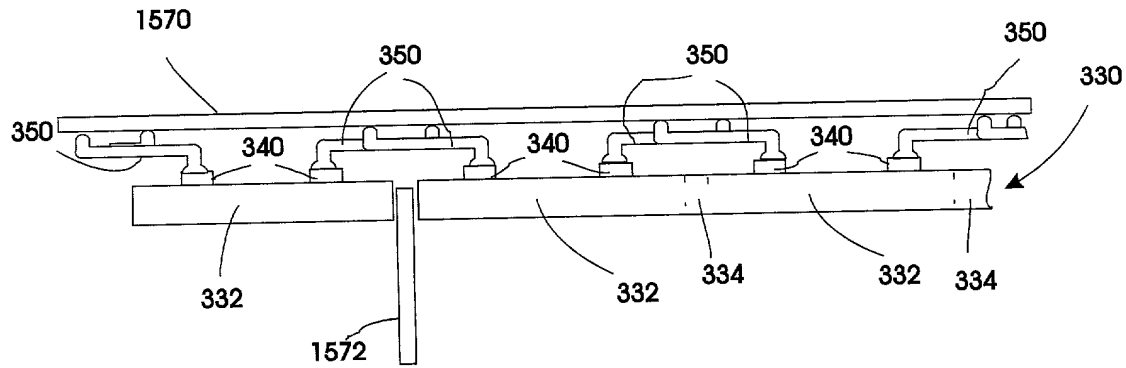


Figure 15D

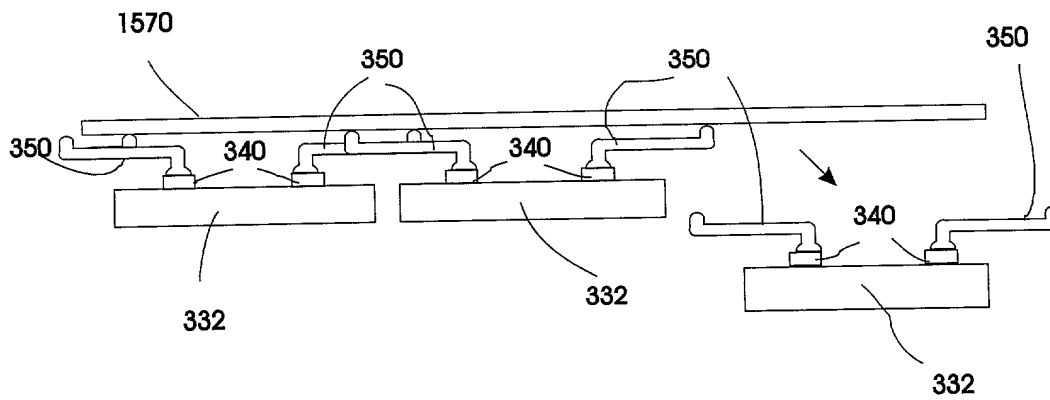


Figure 16A

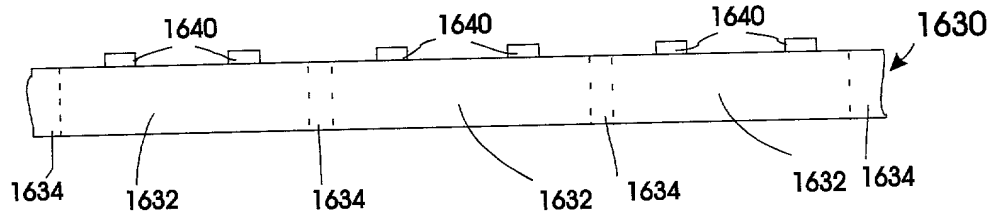


Figure 16B

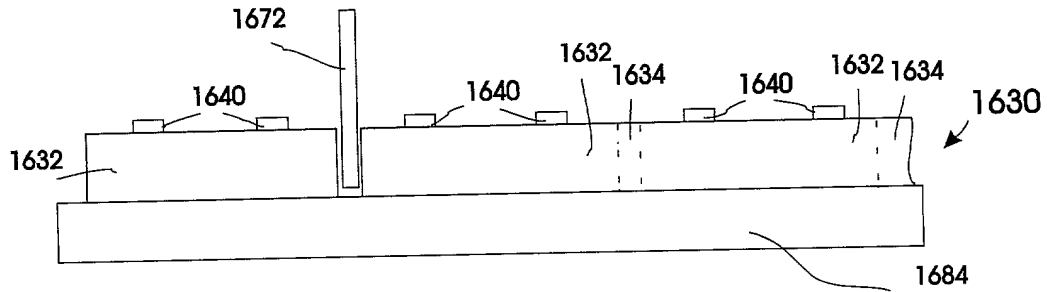


Figure 16C

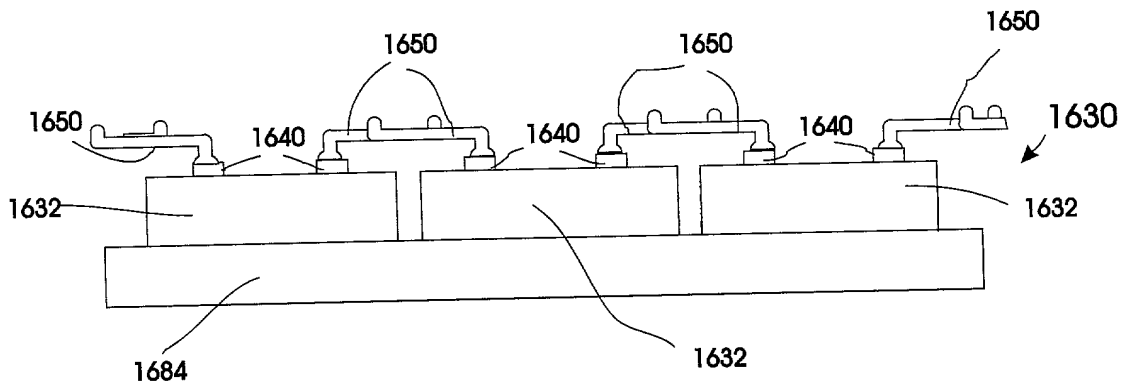


Figure 16D

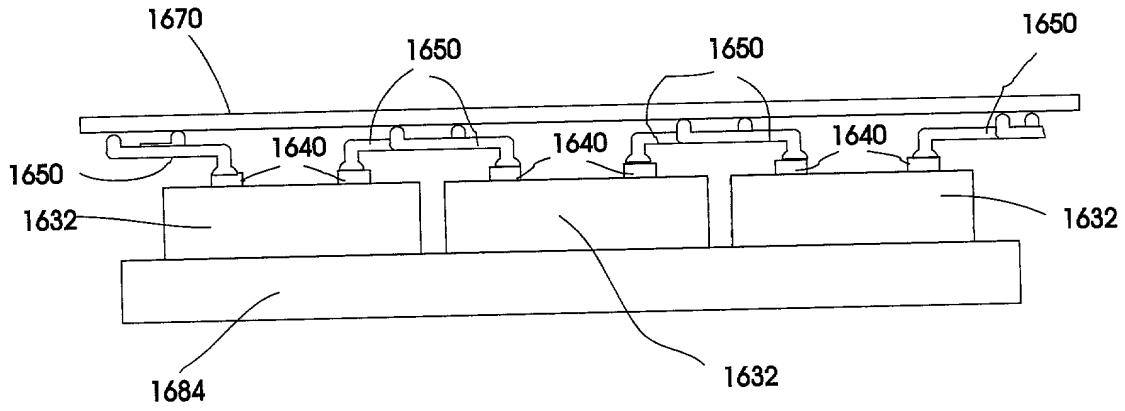


Figure 16E

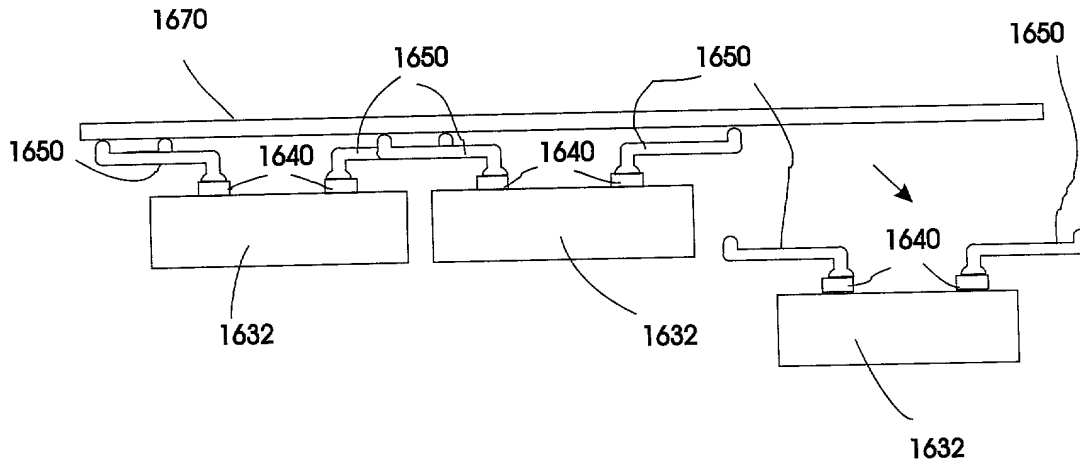


Figure 17A

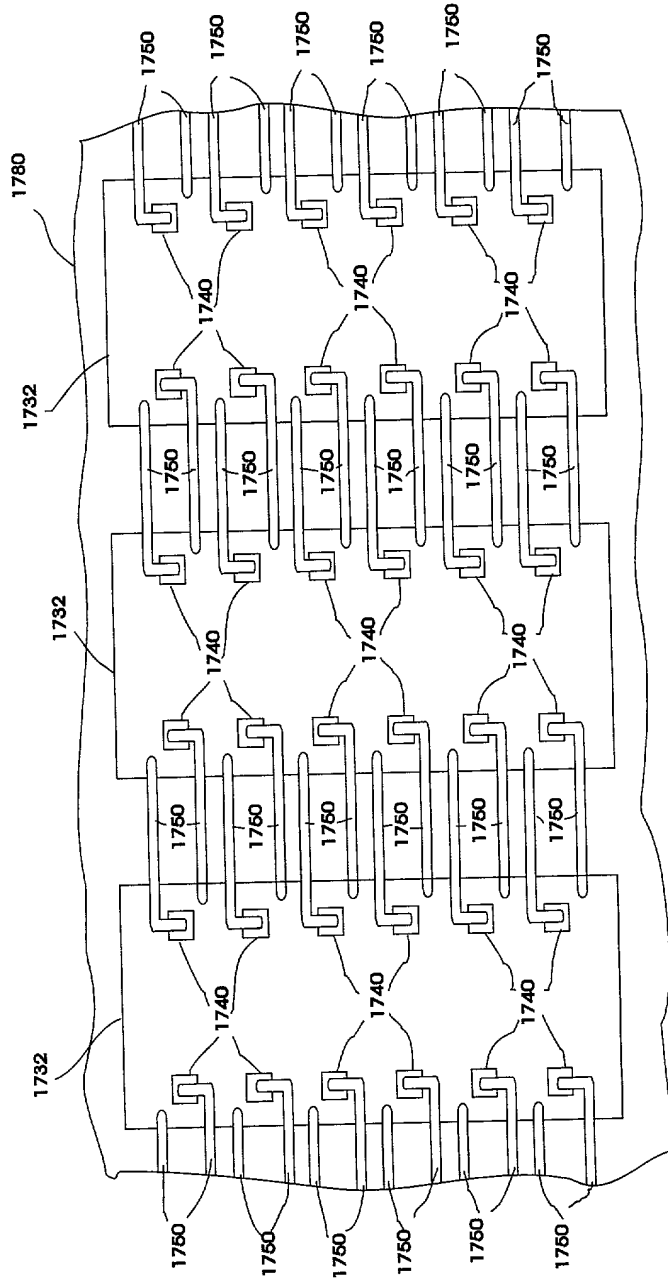


Figure 17B

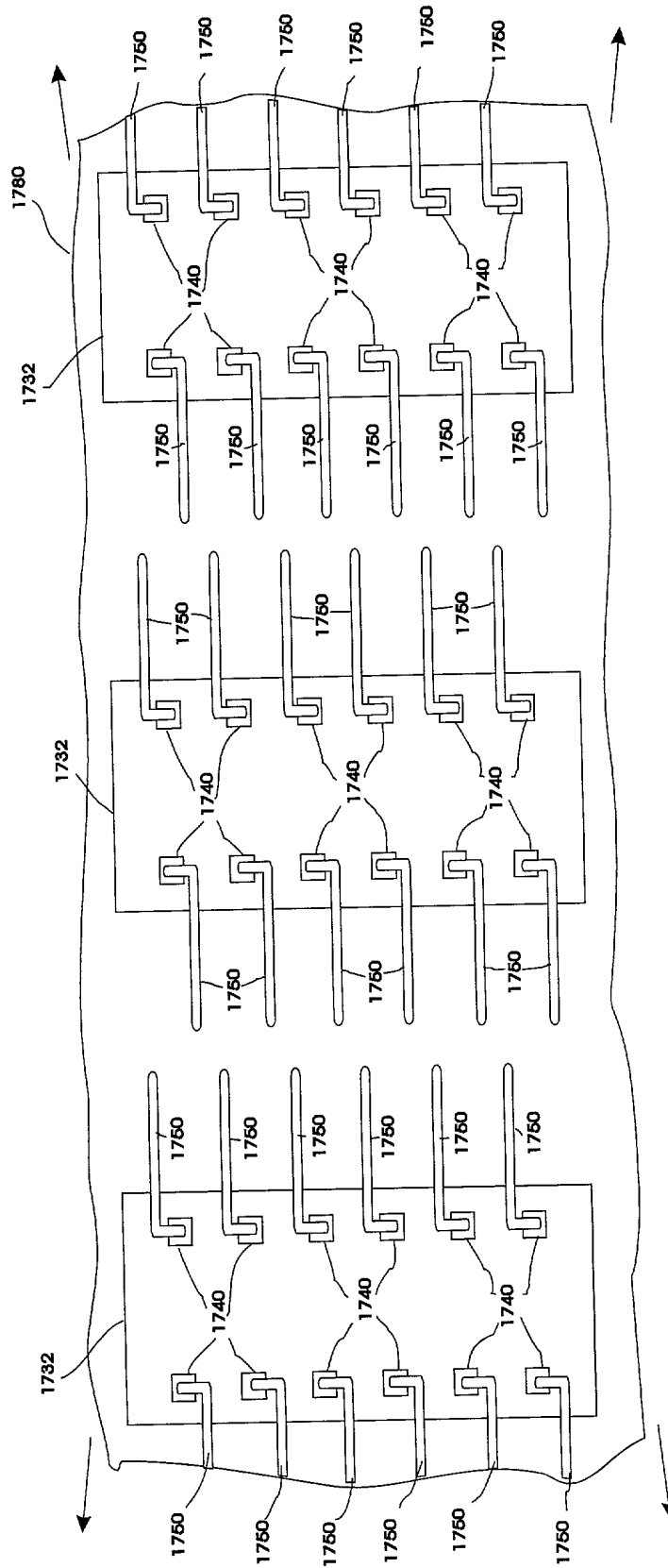
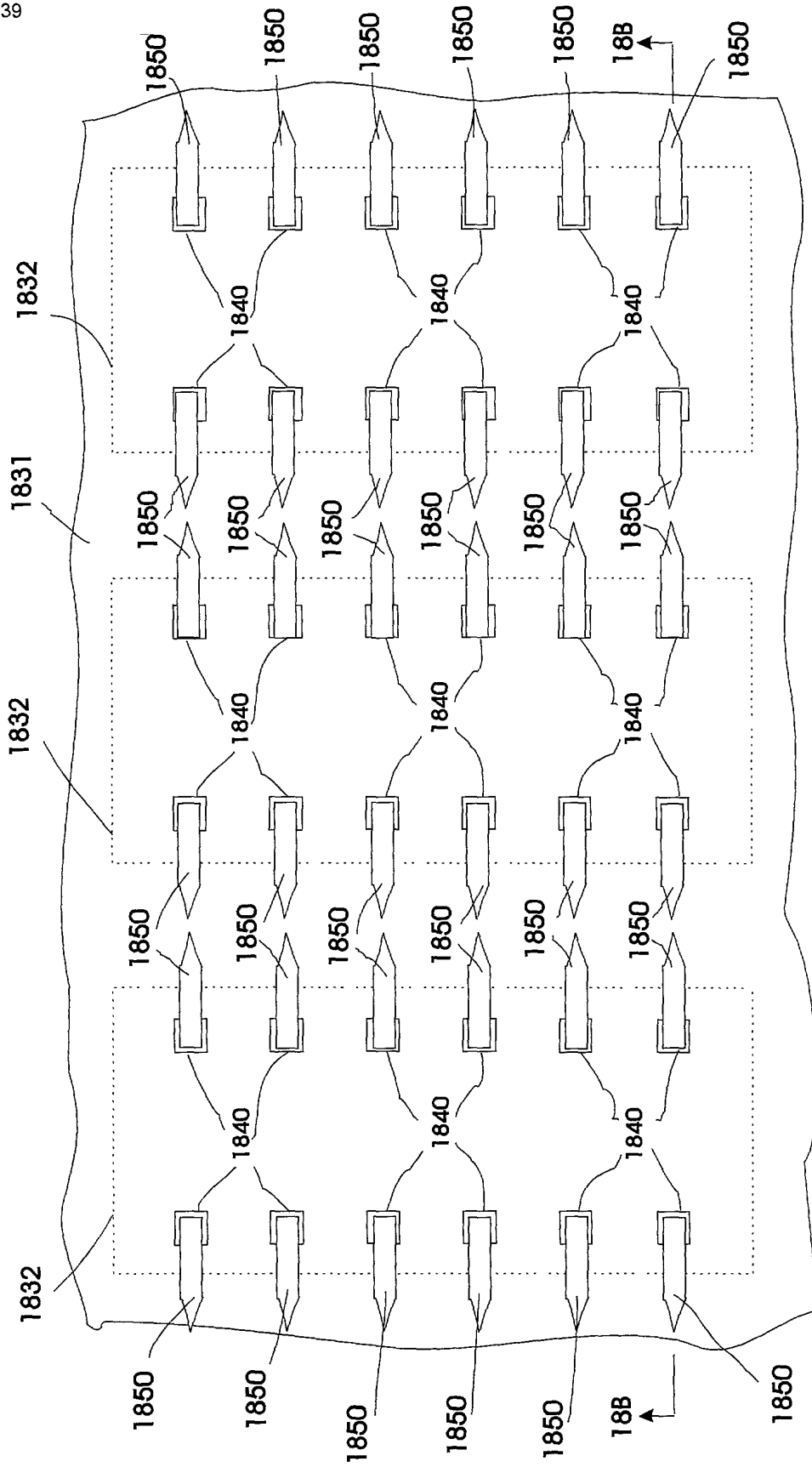


FIG. 18A

Figure 18A



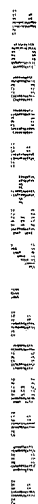


Figure 19

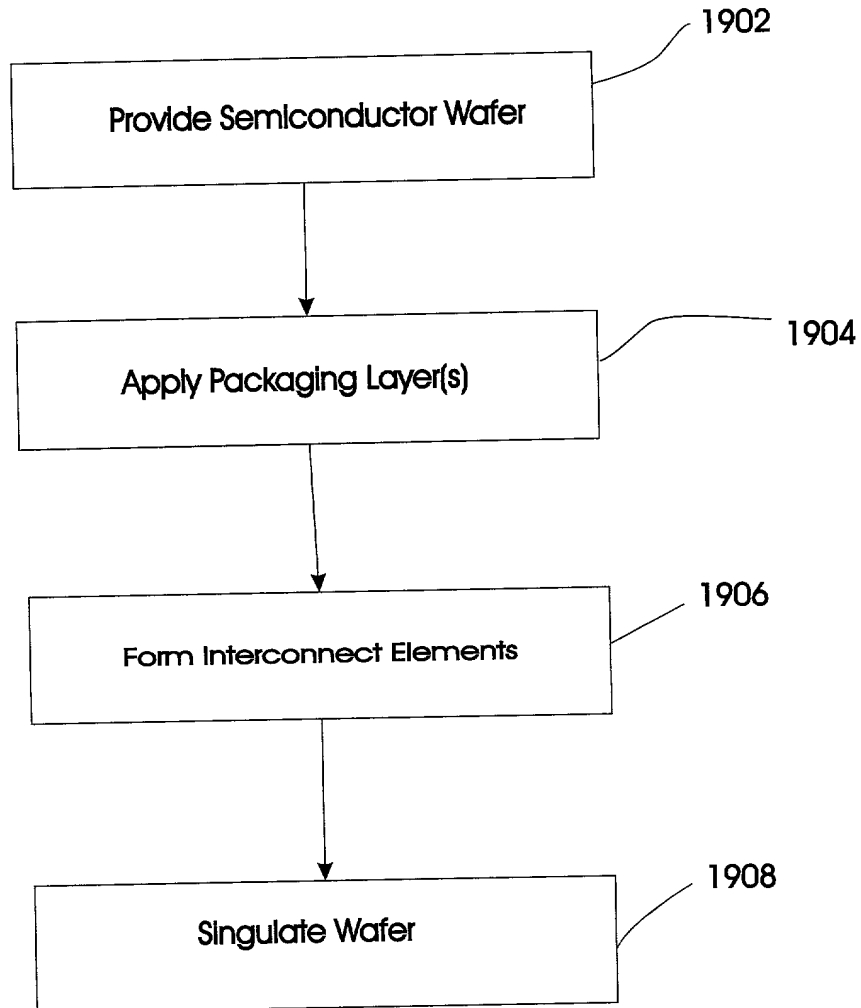




Figure 20A

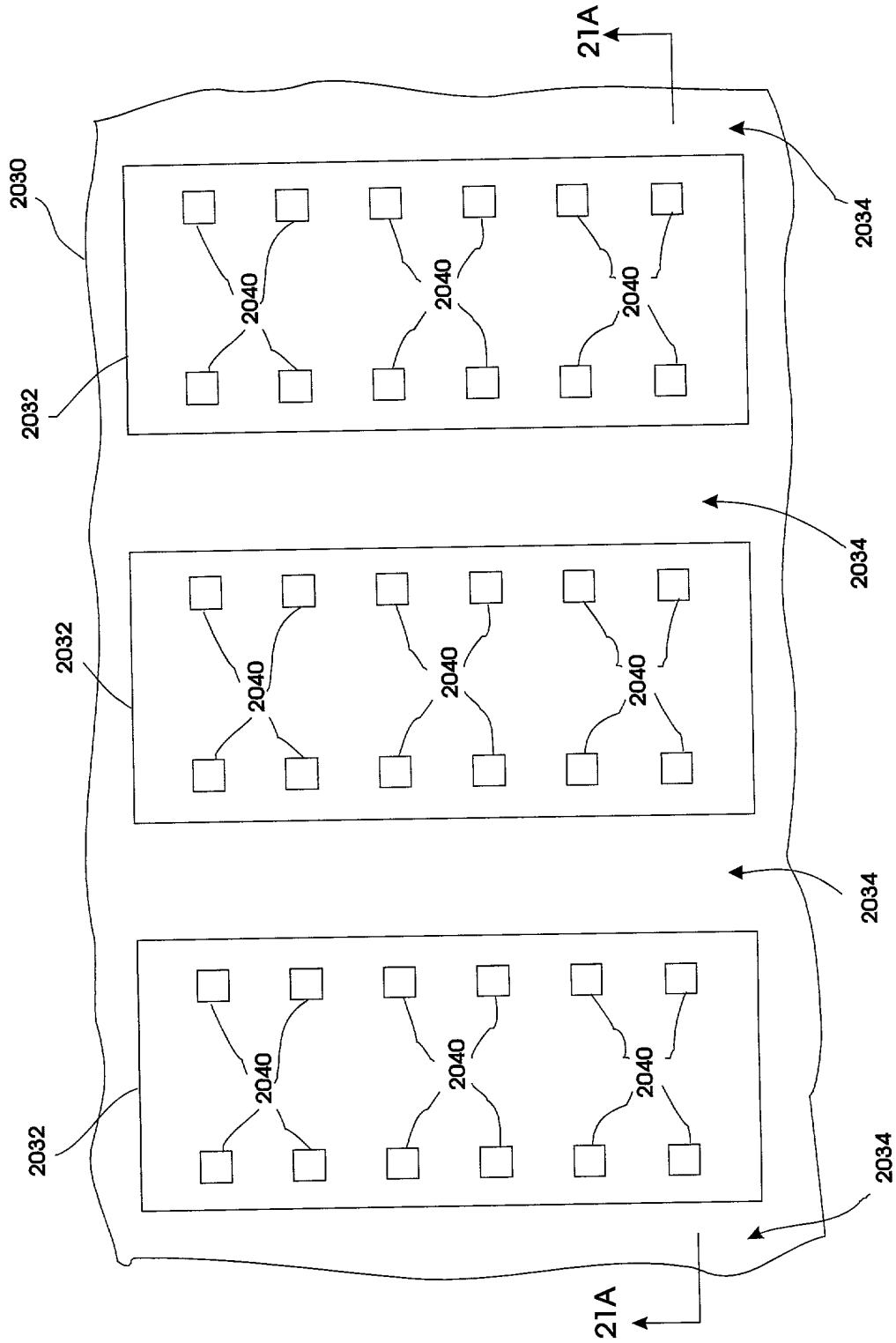


FIG. 20B

Figure 20B

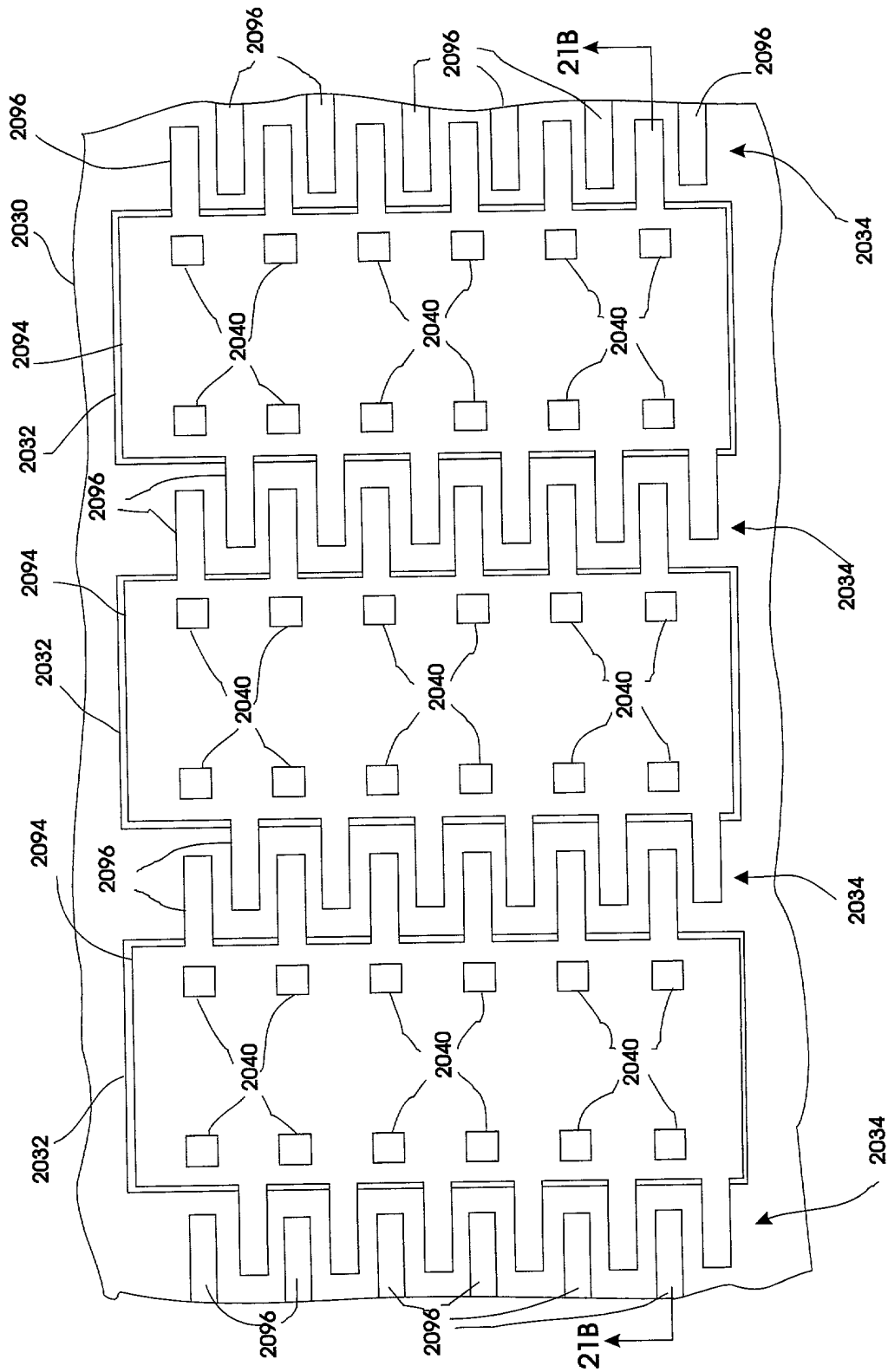


Figure 20C

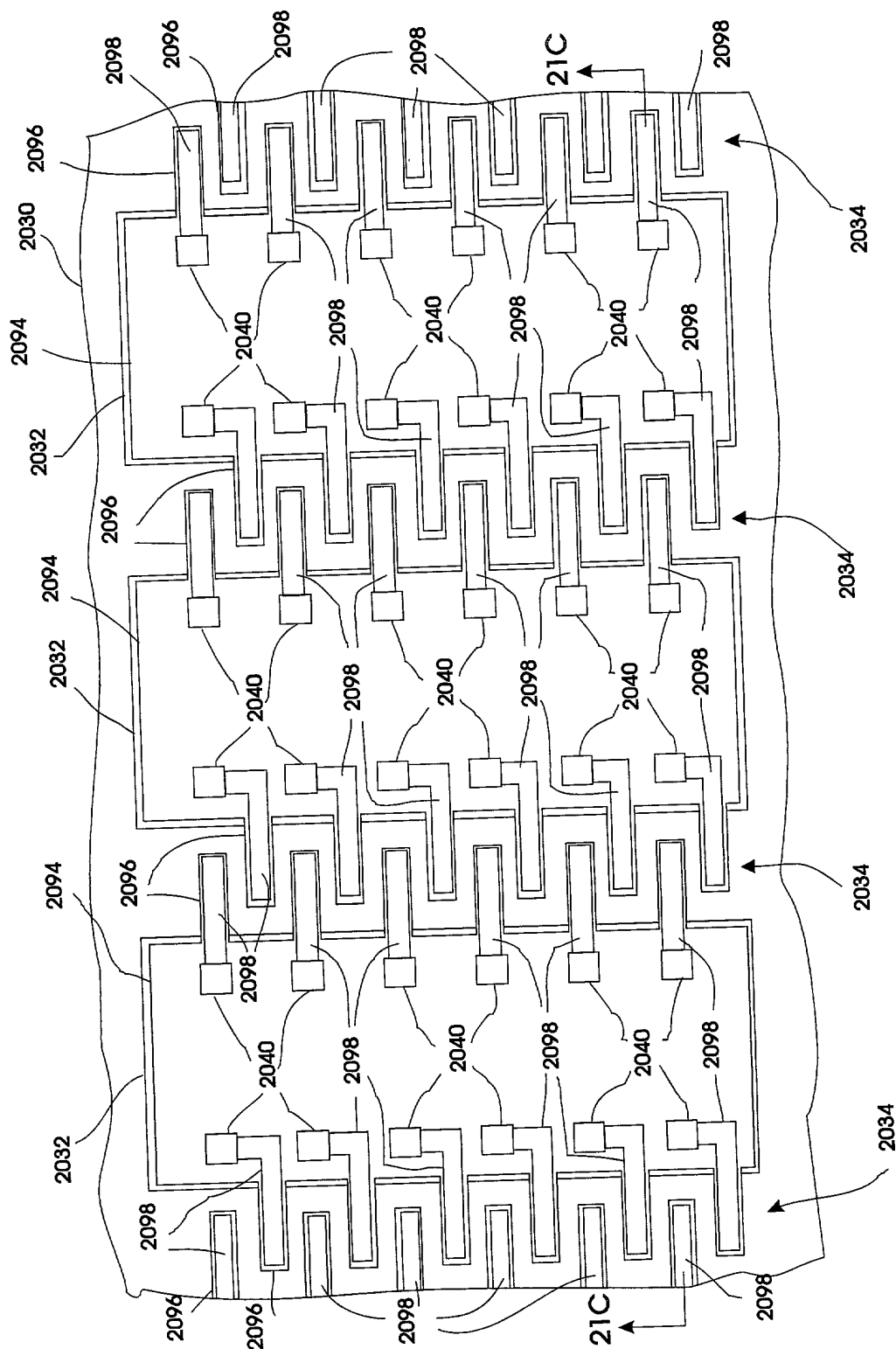


Figure 20D

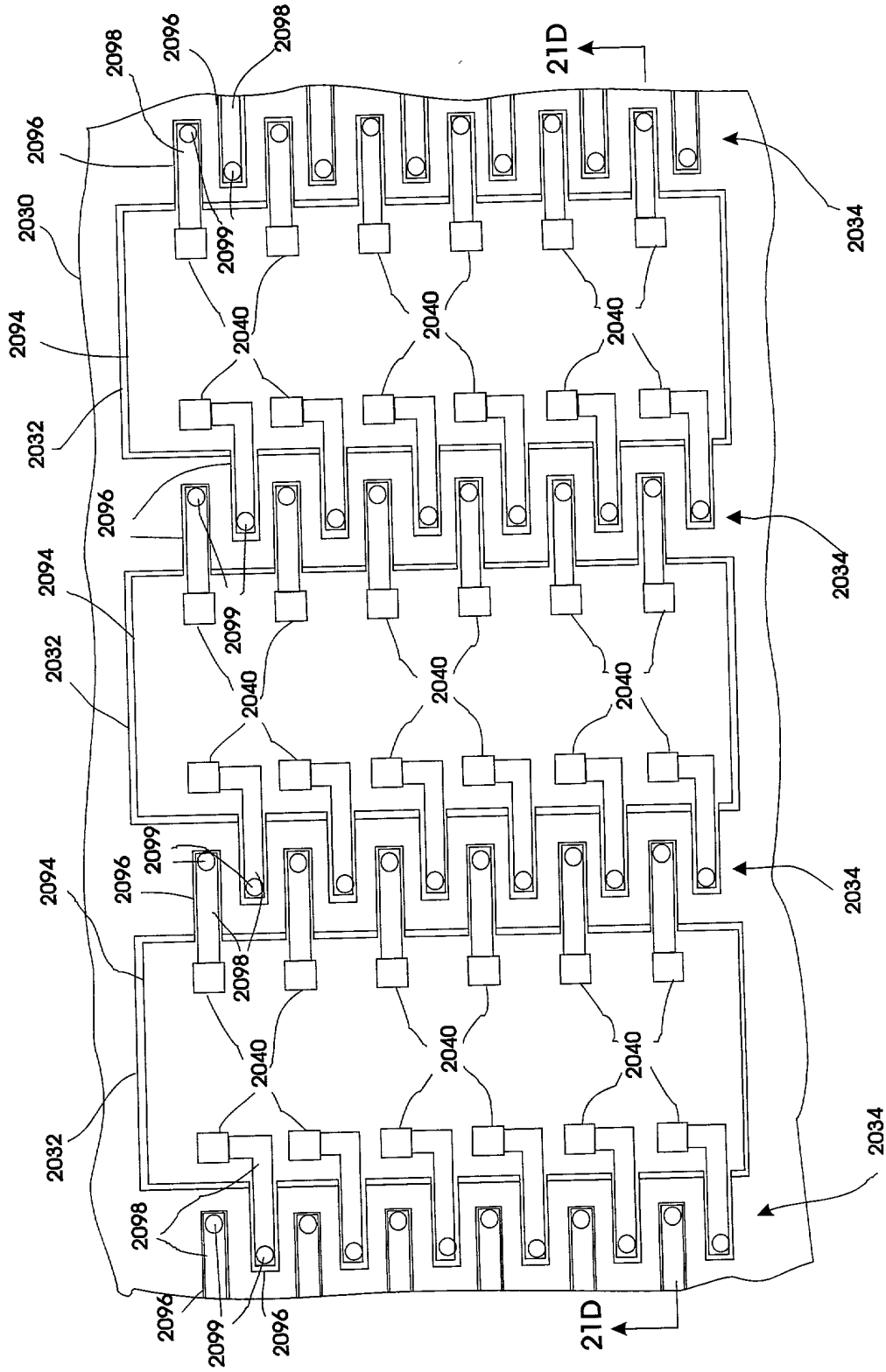


Figure 21A

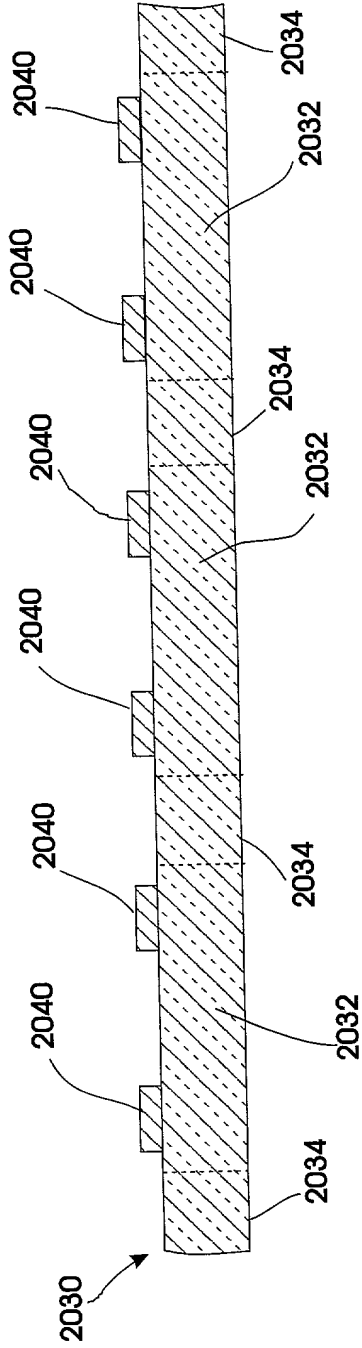
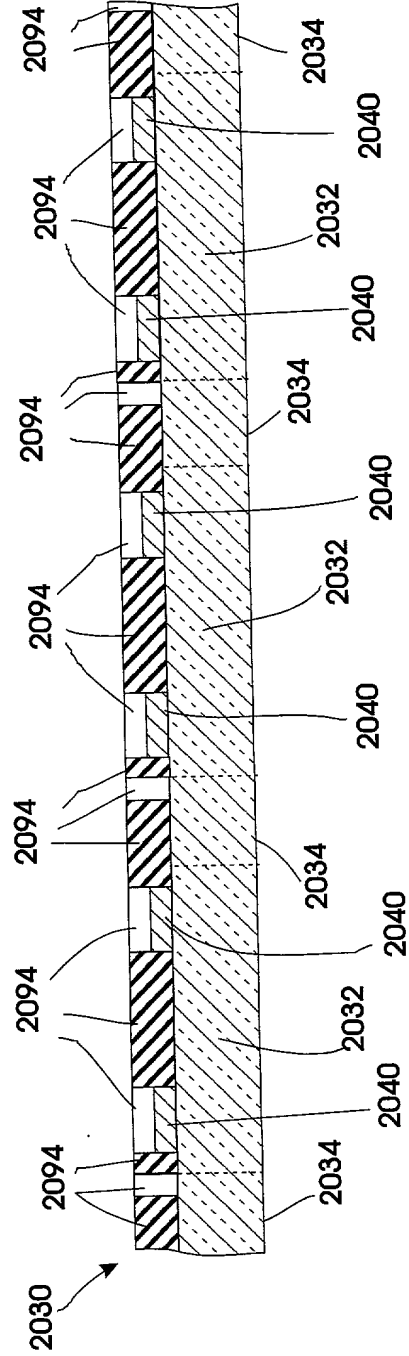


Figure 21B



This diagram shows a cross-sectional view of a semiconductor device. It features a central layer 2098 with a dashed pattern, flanked by layers 2032 and 2034. Above and below these are layers 2040 and 2094, which have diagonal hatching. The top surface is covered by a layer 2030, indicated by an arrow. The bottom surface is covered by a layer 2094, indicated by an arrow. The device is composed of repeating units, each containing a central layer 2098 and surrounding layers 2032, 2034, 2040, and 2094.

Figure 22

